

## 5.0 A H-Bridge with Load Current Feedback

The 33887 is a monolithic H-Bridge Power IC with a load current feedback feature making it ideal for closed-loop DC motor control. The IC incorporates internal control logic, charge pump, gate drive, and low  $R_{DS(ON)}$  MOSFET output circuitry. The 33887 is able to control inductive loads with continuous DC load currents up to 5.0 A, and with peak current active limiting between 5.2 A and 7.8 A. Output loads can be pulse width modulated (PWM-ed) at frequencies up to 10 kHz. The load current feedback feature provides a proportional (1/375th of the load current) constant-current output suitable for monitoring by a microcontroller's A/D input. This feature facilitates the design of closed-loop torque/speed control as well as open load detection.

A Fault Status output pin reports undervoltage, short circuit, and overtemperature conditions. Two independent inputs provide polarity control of two half-bridge totem-pole outputs. Two disable inputs force the H-Bridge outputs to tri-state (exhibit high impedance).

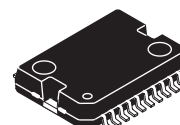
The 33887 is parametrically specified over a temperature range of  $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$  and a voltage range of  $5.0\text{ V} \leq V^+ \leq 28\text{ V}$ . Operation with voltages up to 40 V with derating of the specifications.

### Features

- Fully specified operation 5.0 V to 28 V
- Limited operation with reduced performance up to 40 V
- 120 m $\Omega$   $R_{DS(ON)}$  Typical H-Bridge MOSFETs
- TTL/CMOS Compatible Inputs
- PWM Frequencies up to 10 kHz
- Active Current Limiting (Regulation)
- Fault Status Reporting
- Sleep Mode with Current Draw  $\leq 50\text{ }\mu\text{A}$  (Inputs Floating or Set to Match Default Logic States)
- Pb-Free Packaging Designated by Suffix Codes VW and EK

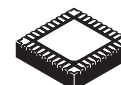
**33887**

### H-BRIDGE

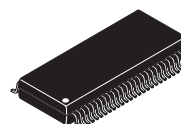


**DH SUFFIX**  
**VW SUFFIX (Pb-FREE)**  
**98ASH70273A**  
**20-PIN HSOP**

**PNB SUFFIX**  
**98ASA10583D**  
**36-PIN PQFN**



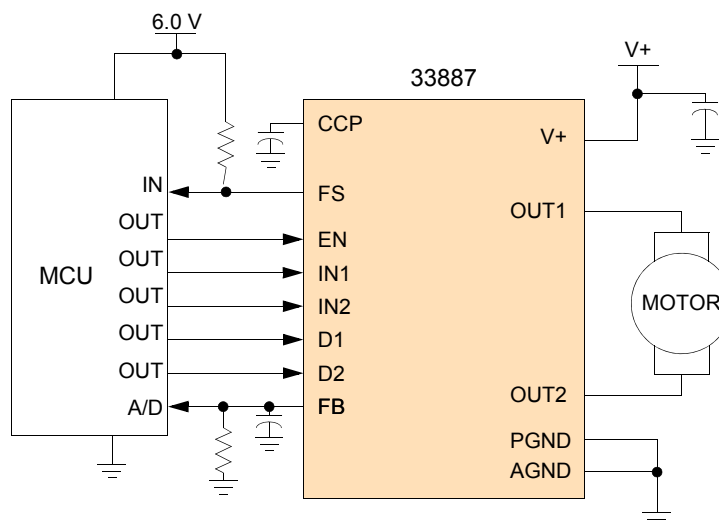
**Bottom View**



**DWB SUFFIX**  
**EK SUFFIX (Pb-FREE)**  
**98ASA10506D**  
**54-PIN SOICW-EP**

### ORDERING INFORMATION

| Device        | Temperature Range ( $T_A$ )                    | Package     |
|---------------|------------------------------------------------|-------------|
| MC33887DH/R2  | $-40^{\circ}\text{C}$ to $125^{\circ}\text{C}$ | 20 HSOP     |
| MC33887VW/R2  |                                                |             |
| MC33887AVW/R2 |                                                |             |
| MC33887PNB/R2 |                                                | 36 PQFN     |
| MC33887DWB/R2 |                                                | 54 SOICW-EP |
| MCZ33887EK/R2 |                                                |             |



**Figure 1. 33887 Simplified Application Diagram**

Freescale Semiconductor, Inc. reserves the right to change the detail specifications, as may be required, to permit improvements in the design of its products.

© Freescale Semiconductor, Inc., 2007 - 2008. All rights reserved.

## INTERNAL BLOCK DIAGRAM

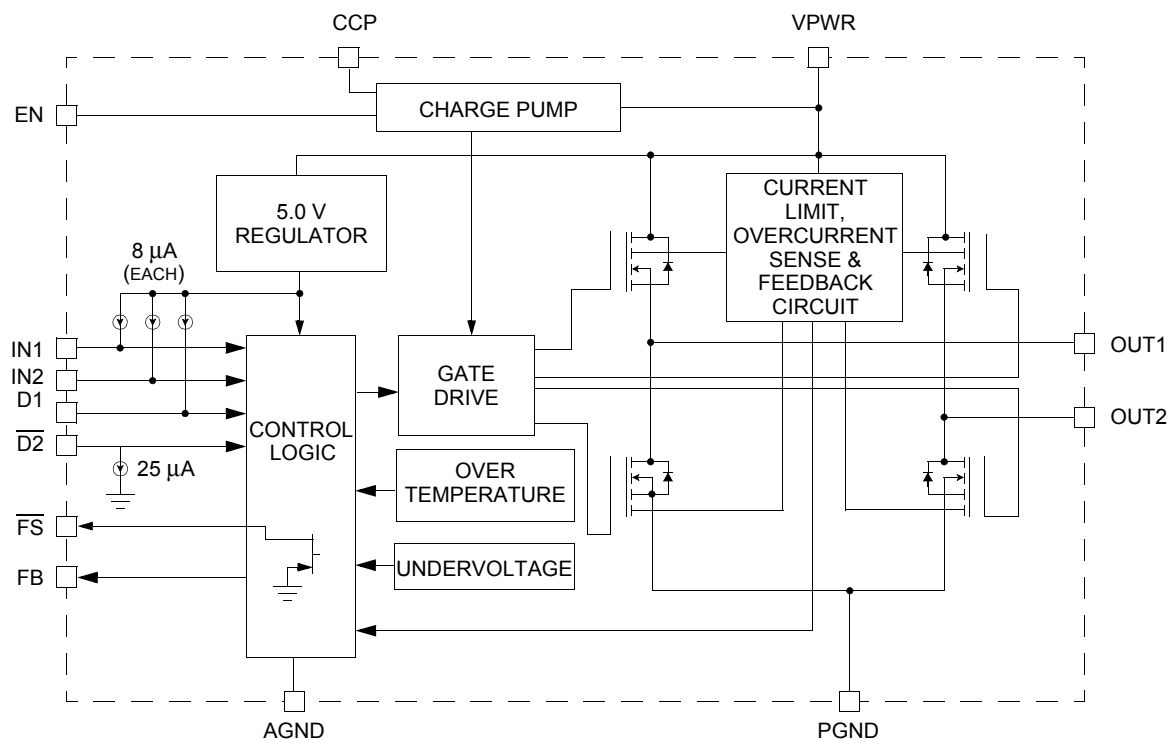


Figure 2. 33887 Simplified Internal Block Diagram

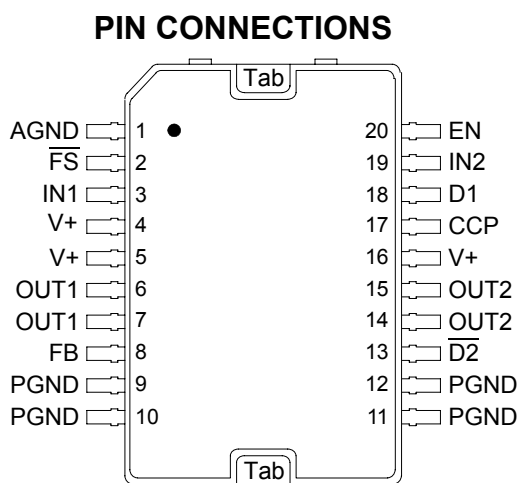


Figure 3. 33887 Pin Connections

Table 1. 33887 HSOP PIN DEFINITIONS

A functional description of each pin can be found in the [Functional Pin DescriptionS](#) section, [page 21](#).

| Pin      | Pin Name               | Formal Name                   | Definition                                                                                                                                                                                                                  |
|----------|------------------------|-------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1        | AGND                   | Analog Ground                 | Low-current analog signal ground.                                                                                                                                                                                           |
| 2        | $\overline{\text{FS}}$ | Fault Status for H-Bridge     | Open drain active LOW Fault Status output requiring a pull-up resistor to 5.0 V.                                                                                                                                            |
| 3        | IN1                    | Logic Input Control 1         | Logic input control of OUT1 (i.e., IN1 logic HIGH = OUT1 HIGH).                                                                                                                                                             |
| 4, 5, 16 | V+                     | Positive Power Supply         | Positive supply connections                                                                                                                                                                                                 |
| 6, 7     | OUT1                   | H-Bridge Output 1             | Output 1 of H-Bridge.                                                                                                                                                                                                       |
| 8        | FB                     | Feedback for H-Bridge         | Current sensing feedback output providing ground referenced 1/375th (0.00266) of H-Bridge high-side current.                                                                                                                |
| 9–12     | PGND                   | Power Ground                  | High-current power ground.                                                                                                                                                                                                  |
| 13       | $\overline{\text{D2}}$ | Disable 2                     | Active LOW input used to simultaneously tri-state disable both H-Bridge outputs. When $\overline{\text{D2}}$ is Logic LOW, both outputs are tri-stated.                                                                     |
| 14, 15   | OUT2                   | H-Bridge Output 2             | Output 2 of H-Bridge.                                                                                                                                                                                                       |
| 17       | CCP                    | Charge Pump Capacitor         | External reservoir capacitor connection for internal charge pump capacitor.                                                                                                                                                 |
| 18       | D1                     | Disable 1                     | Active HIGH input used to simultaneously tri-state disable both H-Bridge outputs. When D1 is Logic HIGH, both outputs are tri-stated.                                                                                       |
| 19       | IN2                    | Logic Input Control 2         | Logic input control of OUT2 (i.e., IN2 logic HIGH = OUT2 HIGH).                                                                                                                                                             |
| 20       | EN                     | Enable                        | Logic input Enable control of device (i.e., EN logic HIGH = full operation, EN logic LOW = Sleep Mode).                                                                                                                     |
| Tab/Pad  | Thermal Interface      | Exposed Pad Thermal Interface | Exposed pad thermal interface for sinking heat from the device.<br><b>Note</b> Must be DC-coupled to analog ground and power ground via very low impedance path to prevent injection of spurious signals into IC substrate. |

## Transparent Top View of Package

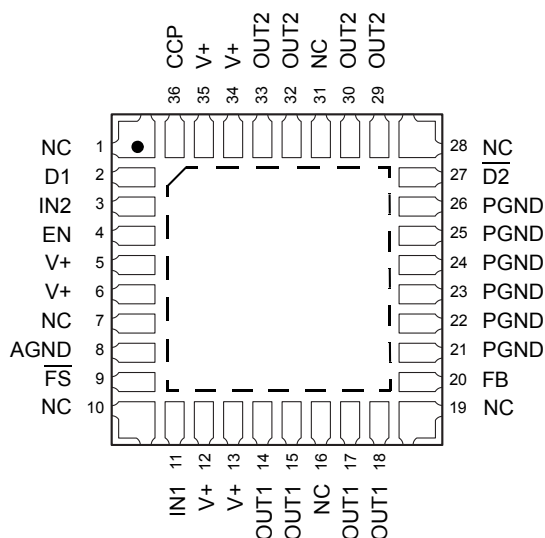


Figure 4. 33887 Pin Connections

Table 2. PQFN PIN DEFINITIONS

A functional description of each pin can be found in the [Functional Pin DescriptionS](#) section, [page 21](#).

| Pin                      | Pin Name               | Formal Name                   | Definition                                                                                                                                                                                                                   |
|--------------------------|------------------------|-------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1, 7, 10, 16, 19, 28, 31 | NC                     | No Connect                    | No internal connection to this pin.                                                                                                                                                                                          |
| 2                        | D1                     | Disable 1                     | Active HIGH input used to simultaneously tri-state disable both H-Bridge outputs. When D1 is Logic HIGH, both outputs are tri-stated.                                                                                        |
| 3                        | IN2                    | Logic Input Control 2         | Logic input control of OUT2 (i.e., IN2 logic HIGH = OUT2 HIGH).                                                                                                                                                              |
| 4                        | EN                     | Enable                        | Logic input Enable control of device (i.e., EN logic HIGH = full operation, EN logic LOW = Sleep Mode).                                                                                                                      |
| 5, 6, 12, 13, 34, 35     | V+                     | Positive Power Supply         | Positive supply connections.                                                                                                                                                                                                 |
| 8                        | AGND                   | Analog Ground                 | Low-current analog signal ground.                                                                                                                                                                                            |
| 9                        | $\overline{\text{FS}}$ | Fault Status for H-Bridge     | Open drain active LOW Fault Status output requiring a pull-up resistor to 5.0 V.                                                                                                                                             |
| 11                       | IN1                    | Logic Input Control 1         | Logic input control of OUT1 (i.e., IN1 logic HIGH = OUT1 HIGH).                                                                                                                                                              |
| 14, 15, 17, 18           | OUT1                   | H-Bridge Output 1             | Output 1 of H-Bridge.                                                                                                                                                                                                        |
| 20                       | FB                     | Feedback for H-Bridge         | Current feedback output providing ground referenced 1/375th ratio of H-Bridge high-side current.                                                                                                                             |
| 21–26                    | PGND                   | Power Ground                  | High-current power ground.                                                                                                                                                                                                   |
| 27                       | $\overline{\text{D2}}$ | Disable 2                     | Active LOW input used to simultaneously tri-state disable both H-Bridge outputs. When D2 is Logic LOW, both outputs are tri-stated.                                                                                          |
| 29, 30, 32, 33           | OUT2                   | H-Bridge Output 2             | Output 2 of H-Bridge.                                                                                                                                                                                                        |
| 36                       | CCP                    | Charge Pump Capacitor         | External reservoir capacitor connection for internal charge pump capacitor.                                                                                                                                                  |
| Pad                      | Thermal Interface      | Exposed Pad Thermal Interface | Exposed pad thermal interface for sinking heat from the device.<br><b>Note:</b> Must be DC-coupled to analog ground and power ground via very low impedance path to prevent injection of spurious signals into IC substrate. |

## Transparent Top View of Package

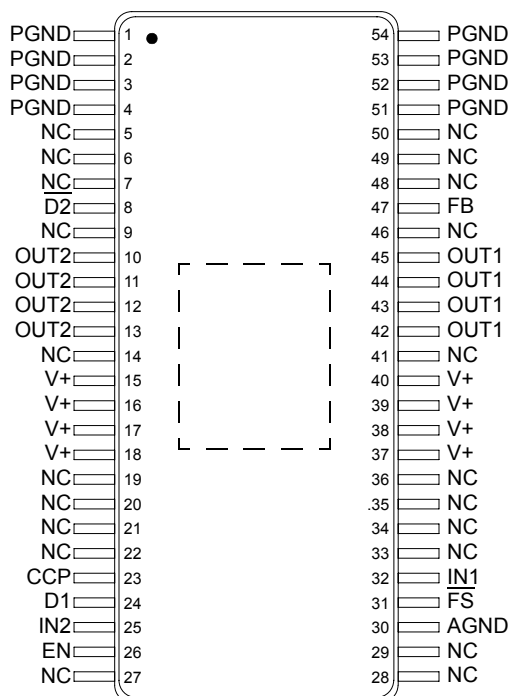


Figure 5. 33887 Pin Connections

Table 3. SOICW-EP PIN DEFINITIONS

A functional description of each pin can be found in the [Functional Pin DescriptionS](#) section, [page 21](#).

| Pin                                                  | Pin Name        | Formal Name               | Definition                                                                                                                                       |
|------------------------------------------------------|-----------------|---------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------|
| 1–4, 51–54                                           | PGND            | Power Ground              | High-current power ground.                                                                                                                       |
| 5–7, 9, 14, 19–22,<br>27–29, 33–36, 41,<br>46, 48–50 | NC              | No Connect                | No internal connection to this pin.                                                                                                              |
| 8                                                    | $\overline{D2}$ | Disable 2                 | Active LOW input used to simultaneously tri-state disable both H-Bridge outputs. When $\overline{D2}$ is Logic LOW, both outputs are tri-stated. |
| 10–13                                                | OUT2            | H-Bridge Output 2         | Output 2 of H-Bridge.                                                                                                                            |
| 15–18, 37–40                                         | V+              | Positive Power Supply     | Positive supply connections.                                                                                                                     |
| 23                                                   | CCP             | Charge Pump Capacitor     | External reservoir capacitor connection for internal charge pump capacitor.                                                                      |
| 24                                                   | D1              | Disable 1                 | Active HIGH input used to simultaneously tri-state disable both H-Bridge outputs. When D1 is Logic HIGH, both outputs are tri-stated.            |
| 25                                                   | IN2             | Logic Input Control 2     | Logic input control of OUT2 (i.e., IN2 logic HIGH = OUT2 HIGH).                                                                                  |
| 26                                                   | EN              | Enable                    | Logic input Enable control of device (i.e., EN logic HIGH = full operation, EN logic LOW = Sleep Mode).                                          |
| 30                                                   | AGND            | Analog Ground             | Low-current analog signal ground.                                                                                                                |
| 31                                                   | $\overline{FS}$ | Fault Status for H-Bridge | Open drain active LOW Fault Status output requiring a pull-up resistor to 5.0 V.                                                                 |
| 32                                                   | IN1             | Logic Input Control 1     | Logic input control of OUT1 (i.e., IN1 logic HIGH = OUT1 HIGH).                                                                                  |

**Table 3. SOICW-EP PIN DEFINITIONS**

A functional description of each pin can be found in the [Functional Pin DescriptionS](#) section, [page 21](#).

| Pin   | Pin Name          | Formal Name                   | Definition                                                                                                                                                                                                                  |
|-------|-------------------|-------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 42–45 | OUT1              | H-Bridge Output 1             | Output 1 of H-Bridge.                                                                                                                                                                                                       |
| 47    | FB                | Feedback for H-Bridge         | Current feedback output providing ground referenced 1/375th ratio of H-Bridge high-side current.                                                                                                                            |
| Pad   | Thermal Interface | Exposed Pad Thermal Interface | Exposed pad thermal interface for sinking heat from the device.<br><b>Note</b> Must be DC-coupled to analog ground and power ground via very low impedance path to prevent injection of spurious signals into IC substrate. |

## ELECTRICAL CHARACTERISTICS

## MAXIMUM RATINGS

## MAXIMUM RATINGS

All voltages are with respect to ground unless otherwise noted.

| Rating                                                        | Symbol            | Value       | Unit |
|---------------------------------------------------------------|-------------------|-------------|------|
| <b>ELECTRICAL RATINGS</b>                                     |                   |             |      |
| Supply Voltage <sup>(1)</sup>                                 | V+                | -0.3 to 40  | V    |
| Input Voltage <sup>(2)</sup>                                  | V <sub>IN</sub>   | -0.3 to 7.0 | V    |
| FS Status Output <sup>(3)</sup>                               | V <sub>FS</sub>   | -0.3 to 7.0 | V    |
| Continuous Current <sup>(4)</sup>                             | I <sub>OUT</sub>  | 5.0         | A    |
| DH Suffix HSOP ESD Voltage <sup>(5)</sup>                     |                   |             | V    |
| Human Body Model                                              |                   |             |      |
| Each Pin to AGND                                              | V <sub>ESD1</sub> | ±1000       |      |
| Each Pin to PGND                                              | V <sub>ESD1</sub> | ±1500       |      |
| Each Pin to V+                                                | V <sub>ESD1</sub> | ±2000       |      |
| Each I/O to All Other I/Os                                    | V <sub>ESD1</sub> | ±2000       |      |
| Machine Model                                                 | V <sub>ESD2</sub> | ±200        |      |
| VW Suffix HSOP, SOICW-EP, and PQFN ESD Voltage <sup>(5)</sup> |                   |             | V    |
| Human Body Model                                              | V <sub>ESD1</sub> | ±2000       |      |
| Machine Model                                                 | V <sub>ESD2</sub> | ±200        |      |

## THERMAL RATINGS

|                                                                   |                   |            |    |
|-------------------------------------------------------------------|-------------------|------------|----|
| Storage Temperature                                               | T <sub>STG</sub>  | -65 to 150 | °C |
| Operating Temperature <sup>(6)</sup>                              |                   |            | °C |
| Ambient                                                           | T <sub>A</sub>    | -40 to 125 |    |
| Junction                                                          | T <sub>J</sub>    | -40 to 150 |    |
| Peak Package Reflow Temperature During Reflow <sup>(7), (8)</sup> | T <sub>PPRT</sub> | Note 8.    | °C |

## Notes

- Performance at voltages greater than 28V is degraded. See [Electrical Performance Curves on page 18](#) and 19 for typical performance. Extended operation at higher voltages has not been fully characterized and may reduce the operational lifetime.
- Exceeding the input voltage on IN1, IN2, EN, D1, or  $\overline{D2}$  may cause a malfunction or permanent damage to the device.
- Exceeding the pull-up resistor voltage on the open Drain  $\overline{FS}$  pin may cause permanent damage to the device.
- Continuous current capability so long as junction temperature is  $\leq 150^{\circ}\text{C}$ .
- ESD1 testing is performed in accordance with the Human Body Model ( $C_{ZAP} = 100\text{ pF}$ ,  $R_{ZAP} = 1500\ \Omega$ ), ESD2 testing is performed in accordance with the Machine Model ( $C_{ZAP} = 200\text{ pF}$ ,  $R_{ZAP} = 0\ \Omega$ ).
- The limiting factor is junction temperature, taking into account the power dissipation, thermal resistance, and heat sinking provided. Brief nonrepetitive excursions of junction temperature above  $150^{\circ}\text{C}$  can be tolerated as long as duration does not exceed 30 seconds maximum. (nonrepetitive events are defined as not occurring more than once in 24 hours.)
- Pin soldering temperature limit is for 10 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause malfunction or permanent damage to the device.
- Freescall's Package Reflow capability meets Pb-free requirements for JEDEC standard J-STD-020C. For Peak Package Reflow Temperature and Moisture Sensitivity Levels (MSL), Go to [www.freescale.com](http://www.freescale.com), search by part number [e.g. remove prefixes/suffixes and enter the core ID to view all orderable parts. (i.e. MC33xxxD enter 33xxx)], and review parametrics.

**MAXIMUM RATINGS (continued)**

All voltages are with respect to ground unless otherwise noted.

| Rating                                                                                                                               | Symbol           | Value                | Unit |
|--------------------------------------------------------------------------------------------------------------------------------------|------------------|----------------------|------|
| <b>THERMAL RESISTANCE (AND PACKAGE DISSIPATION) RATINGS</b> <sup>(9), (10), (11), (12)</sup>                                         |                  |                      |      |
| Junction-to-Board (Bottom Exposed Pad Soldered to Board)<br>HSOP (6.0 W)<br>PQFN (4.0 W)<br>SOICW-EP (2.0 W)                         | $R_{\theta JB}$  | ~7.0<br>~8.0<br>~9.0 | °C/W |
| Junction-to-Ambient, Natural Convection, Single-Layer Board (1s) <sup>(13)</sup><br>HSOP (6.0 W)<br>PQFN (4.0 W)<br>SOICW-EP (2.0 W) | $R_{\theta JA}$  | ~41<br>~50<br>~62    | °C/W |
| Junction-to-Ambient, Natural Convection, Four-Layer Board (2s2p) <sup>(14)</sup><br>HSOP (6.0 W)<br>PQFN (4.0 W)<br>SOICW-EP (2.0 W) | $R_{\theta JMA}$ | ~18<br>~21<br>~23    | °C/W |
| Junction-to-Case (Exposed Pad) <sup>(15)</sup><br>HSOP (6.0 W)<br>PQFN (4.0 W)<br>SOICW-EP (2.0 W)                                   | $R_{\theta JC}$  | ~0.8<br>~1.2<br>~2.0 | °C/W |

Notes

- 9 The limiting factor is junction temperature, taking into account the power dissipation, thermal resistance, and heat sinking.
- 10 Exposed heatsink pad plus the power and ground pins comprise the main heat conduction paths. The actual  $R_{\theta JB}$  (junction-to-PC board) values will vary depending on solder thickness and composition and copper trace thickness. Maximum current at maximum die temperature represents ~16 W of conduction loss heating in the diagonal pair of output MOSFETs. Therefore, the  $R_{\theta JC}$ -total must be less than 5.0 °C/W for maximum load at 70°C ambient. Module thermal design must be planned accordingly.
- 11 Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- 12 Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- 13 Per SEMI G38-87 and JEDEC JESD51-2 with the single-layer board (JESD51-3) horizontal.
- 14 Per JEDEC JESD51-6 with the board horizontal.
- 15 Indicates the maximum thermal resistance between the die and the exposed pad surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature.

## STATIC ELECTRICAL CHARACTERISTICS

**Table 4. STATIC ELECTRICAL CHARACTERISTICS**

Characteristics noted under conditions  $5.0\text{ V} \leq V_+ \leq 28\text{ V}$  and  $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$  unless otherwise noted. Typical values noted reflect the approximate parameter mean at  $T_A = 25^\circ\text{C}$  under nominal conditions unless otherwise noted.

| Characteristic                                                                               | Symbol             | Min       | Typ    | Max     | Unit          |
|----------------------------------------------------------------------------------------------|--------------------|-----------|--------|---------|---------------|
| <b>POWER SUPPLY</b>                                                                          |                    |           |        |         |               |
| Operating Voltage Range <sup>(16)</sup>                                                      | $V_+$              | 5.0       | –      | 28      | V             |
| Sleep State Supply Current <sup>(17)</sup><br>$I_{OUT} = 0\text{ A}$ , $V_{EN} = 0\text{ V}$ | $I_{Q(SLEEP)}$     | –         | 25     | 50      | $\mu\text{A}$ |
| Standby Supply Current<br>$I_{OUT} = 0\text{ A}$ , $V_{EN} = 5.0\text{ V}$                   | $I_{Q(STANDBY)}$   | –         | –      | 20      | mA            |
| Threshold Supply Voltage                                                                     |                    |           |        |         |               |
| Switch-OFF                                                                                   | $V_{+(THRES-OFF)}$ | 4.15      | 4.4    | 4.65    | V             |
| Switch-ON                                                                                    | $V_{+(THRES-ON)}$  | 4.5       | 4.75   | 5.0     | V             |
| Hysteresis                                                                                   | $V_{+(HYS)}$       | 150       | –      | –       | mV            |
| <b>CHARGE PUMP</b>                                                                           |                    |           |        |         |               |
| Charge Pump Voltage<br>$V_+ = 5.0\text{ V}$<br>$8.0\text{ V} \leq V_+ \leq 28\text{ V}$      | $V_{CP} - V_+$     | 3.35<br>– | –<br>– | –<br>20 | V             |
| <b>CONTROL INPUTS</b>                                                                        |                    |           |        |         |               |
| Input Voltage ( $IN1$ , $IN2$ , $D1$ , $\overline{D2}$ )                                     |                    |           |        |         | V             |
| Threshold HIGH                                                                               | $V_{IH}$           | 3.5       | –      | –       |               |
| Threshold LOW                                                                                | $V_{IL}$           | –         | –      | 1.4     |               |
| Hysteresis                                                                                   | $V_{HYS}$          | 0.7       | 1.0    | –       |               |
| Input Current ( $IN1$ , $IN2$ , $D1$ )<br>$V_{IN} = 0.0\text{ V}$                            | $I_{INP}$          | –200      | –80    | –       | $\mu\text{A}$ |
| Input Current ( $\overline{D2}$ , $EN$ )<br>$V_{\overline{D2}} = 5.0\text{ V}$               | $I_{INP}$          | –         | 25     | 100     | $\mu\text{A}$ |

## Notes

- 16 Specifications are characterized over the range of  $5.0\text{ V} \leq V_+ \leq 28\text{ V}$ . See [See Electrical Performance Curves on page 18](#) and 19 and the [See Functional Description on page 21](#) for information about operation outside of this range.
- 17  $I_{Q(sleep)}$  is with sleep mode function enabled.

**Table 4. STATIC ELECTRICAL CHARACTERISTICS**

Characteristics noted under conditions  $5.0\text{ V} \leq V_+ \leq 28\text{ V}$  and  $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$  unless otherwise noted. Typical values noted reflect the approximate parameter mean at  $T_A = 25^\circ\text{C}$  under nominal conditions unless otherwise noted.

| Characteristic                                                                                                                                                                                                                                      | Symbol                 | Min                             | Typ                           | Max                                  | Unit                       |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------|---------------------------------|-------------------------------|--------------------------------------|----------------------------|
| <b>POWER SUPPLY</b>                                                                                                                                                                                                                                 |                        |                                 |                               |                                      |                            |
| <b>POWER OUTPUTS (OUT1, OUT2)</b>                                                                                                                                                                                                                   |                        |                                 |                               |                                      |                            |
| Output ON-Resistance <sup>(18)</sup><br>$5.0\text{ V} \leq V_+ \leq 28\text{ V}, T_J = 25^\circ\text{C}$<br>$8.0\text{ V} \leq V_+ \leq 28\text{ V}, T_J = 150^\circ\text{C}$<br>$5.0\text{ V} \leq V_+ \leq 8.0\text{ V}, T_J = 150^\circ\text{C}$ | $R_{DS(ON)}$           | –<br>–<br>–                     | 120<br>–<br>–                 | –<br>225<br>300                      | mΩ                         |
| Active Current Limiting Threshold (via Internal Constant OFF-Time PWM) on Low-Side MOSFETs <sup>(19)</sup>                                                                                                                                          | $I_{LIM}$              | 5.2                             | 6.5                           | 7.8                                  | A                          |
| High-Side Short Circuit Detection Threshold                                                                                                                                                                                                         | $I_{SCH}$              | 11                              | –                             | –                                    | A                          |
| Low-Side Short Circuit Detection Threshold                                                                                                                                                                                                          | $I_{SCL}$              | 8.0                             | –                             | –                                    | A                          |
| Leakage Current <sup>(20)</sup><br>$V_{OUT} = V_+$<br>$V_{OUT} = \text{Ground}$                                                                                                                                                                     | $I_{OUT(LEAK)}$        | –<br>–                          | 100<br>30                     | 200<br>60                            | μA                         |
| Output MOSFET Body Diode Forward Voltage Drop<br>$I_{OUT} = 3.0\text{ A}$                                                                                                                                                                           | $V_F$                  | –                               | –                             | 2.0                                  | V                          |
| Overtemperature Shutdown<br>Thermal Limit<br>Hysteresis                                                                                                                                                                                             | $T_{LIM}$<br>$T_{HYS}$ | 175<br>10                       | –<br>–                        | 225<br>30                            | °C                         |
| <b>HIGH-SIDE CURRENT SENSE FEEDBACK</b>                                                                                                                                                                                                             |                        |                                 |                               |                                      |                            |
| Feedback Current<br>$I_{OUT} = 0\text{ mA}$<br>$I_{OUT} = 500\text{ mA}$<br>$I_{OUT} = 1.5\text{ A}$<br>$I_{OUT} = 3.0\text{ A}$<br>$I_{OUT} = 6.0\text{ A}$                                                                                        | $I_{FB}$               | –<br>1.07<br>3.6<br>7.2<br>14.4 | –<br>1.33<br>4.0<br>8.0<br>16 | 600<br>1.68<br>4.62<br>9.24<br>18.48 | μA<br>mA<br>mA<br>mA<br>mA |
| <b>FAULT STATUS <sup>(21)</sup></b>                                                                                                                                                                                                                 |                        |                                 |                               |                                      |                            |
| Fault Status Leakage Current <sup>(22)</sup><br>$V_{FS} = 5.0\text{ V}$                                                                                                                                                                             | $I_{FS(LEAK)}$         | –                               | –                             | 10                                   | μA                         |
| Fault Status SET Voltage <sup>(23)</sup><br>$I_{FS} = 300\text{ μA}$                                                                                                                                                                                | $V_{FS(LOW)}$          | –                               | –                             | 1.0                                  | V                          |

Notes

- 18 Output-ON resistance as measured from output to  $V_+$  and ground.
- 19 Active current limitation applies only for the low-side MOSFETs.
- 20 Outputs switched OFF with D1 or D2.
- 21 Fault Status output is an open Drain output requiring a pull-up resistor to 5.0 V.
- 22 Fault Status Leakage Current is measured with Fault Status HIGH and *not* SET.
- 23 Fault Status Set Voltage is measured with Fault Status LOW and SET with  $I_{FS} = 300\text{ μA}$ .

## DYNAMIC ELECTRICAL CHARACTERISTICS

**Table 5. DYNAMIC ELECTRICAL CHARACTERISTICS**

Characteristics noted under conditions  $5.0\text{ V} \leq V_+ \leq 28\text{ V}$  and  $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$  unless otherwise noted. Typical values noted reflect the approximate parameter mean at  $T_A = 25^\circ\text{C}$  under nominal conditions unless otherwise noted.

| Characteristic                                                                                     | Symbol                       | Min | Typ  | Max | Unit          |
|----------------------------------------------------------------------------------------------------|------------------------------|-----|------|-----|---------------|
| <b>TIMING CHARACTERISTICS</b>                                                                      |                              |     |      |     |               |
| PWM Frequency <sup>(24)</sup>                                                                      | $f_{\text{PWM}}$             | –   | 10   | –   | kHz           |
| Maximum Switching Frequency During Active Current Limiting <sup>(25)</sup>                         | $f_{\text{MAX}}$             | –   | –    | 20  | kHz           |
| Output ON Delay <sup>(26)</sup><br>$V_+ = 14\text{ V}$                                             | $t_{\text{D(ON)}}$           | –   | –    | 18  | $\mu\text{s}$ |
| Output OFF Delay <sup>(26)</sup><br>$V_+ = 14\text{ V}$                                            | $t_{\text{D(OFF)}}$          | –   | –    | 18  | $\mu\text{s}$ |
| $I_{\text{LIM}}$ Output Constant-OFF Time for Low-Side MOSFETs <sup>(27), (28)</sup>               | $t_{\text{A}}$               | 15  | 20.5 | 26  | $\mu\text{s}$ |
| $I_{\text{LIM}}$ Blanking Time for Low-Side MOSFETs <sup>(29), (28)</sup>                          | $t_{\text{B}}$               | 12  | 16.5 | 21  | $\mu\text{s}$ |
| Output Rise and Fall Time <sup>(30)</sup><br>$V_+ = 14\text{ V}$ , $I_{\text{OUT}} = 3.0\text{ A}$ | $t_{\text{F}}, t_{\text{R}}$ | 2.0 | 5.0  | 8.0 | $\mu\text{s}$ |
| Disable Delay Time <sup>(31)</sup>                                                                 | $t_{\text{D(DISABLE)}}$      | –   | –    | 8.0 | $\mu\text{s}$ |
| Power-ON Delay Time <sup>(32)</sup>                                                                | $t_{\text{POD}}$             | –   | 1.0  | 5.0 | ms            |
| Wake-Up Delay Time <sup>(32)</sup>                                                                 | $t_{\text{WUD}}$             | –   | 1.0  | 5.0 | ms            |
| Output MOSFET Body Diode Reverse Recovery Time <sup>(33)</sup>                                     | $t_{\text{RR}}$              | 100 | –    | –   | ns            |

## Notes

- 24 The outputs can be PWM-controlled from an external source. This is typically done by holding one input high while applying a PWM pulse train to the other input. The maximum PWM frequency obtainable is a compromise between switching losses and switching frequency. See Typical Switching Waveforms, [Figures 12 through 19](#), pp. 14–17.
- 25 The Maximum Switching Frequency during active current limiting is internally implemented. The internal current limit circuitry produces a constant-OFF-time pulse-width modulation of the output current. The output load's inductance, capacitance, and resistance characteristics affect the total switching period (OFF-time + ON-time) and thus the PWM frequency during current limit.
- 26 Output Delay is the time duration from the midpoint of the IN1 or IN2 input signal to the 10% or 90% point (dependent on the transition direction) of the OUT1 or OUT2 signal. If the output is transitioning HIGH-to-LOW, the delay is from the midpoint of the input signal to the 90% point of the output response signal. If the output is transitioning LOW-to-HIGH, the delay is from the midpoint of the input signal to the 10% point of the output response signal. See [Figure 6](#), page 12.
- 27  $I_{\text{LIM}}$  Output Constant-OFF Time is the time during which the internal constant-OFF time PWM current regulation circuit has tri-stated the output bridge.
- 28 Load currents ramping up to the current regulation threshold become limited at the  $I_{\text{LIM}}$  value. The short circuit currents possess a di/dt that ramps up to the  $I_{\text{SCH}}$  or  $I_{\text{SCL}}$  threshold during the  $I_{\text{LIM}}$  blanking time, registering as a short circuit event detection and causing the shutdown circuitry to force the output into an immediate tri-state latch-OFF. See [Figures 10 and 11](#), page 13. Operation in Current Limit mode may cause junction temperatures to rise. Junction temperatures above  $\sim 160^\circ\text{C}$  will cause the output current limit threshold to progressively “fold back”, or decrease with temperature, until  $\sim 175^\circ\text{C}$  is reached, after which the  $T_{\text{LIM}}$  thermal latch-OFF will occur. Permissible operation within this fold-back region is limited to nonrepetitive transient events of duration not to exceed 30 seconds. See [Figure 9](#), page 12.
- 29  $I_{\text{LIM}}$  Blanking Time is the time during which the current regulation threshold is ignored so that the short-circuit detection threshold comparators may have time to act.
- 30 Rise Time is from the 10% to the 90% level and Fall Time is from the 90% to the 10% level of the output signal. See [Figure 8](#), page 12.
- 31 Disable Delay Time is the time duration from the midpoint of the D (disable) input signal to 10% of the output tri-state response. See [Figure 7](#), page 12.
- 32 Parameter has been characterized but not production tested.
- 33 Parameter is guaranteed by design but not production tested.

## TIMING DIAGRAMS

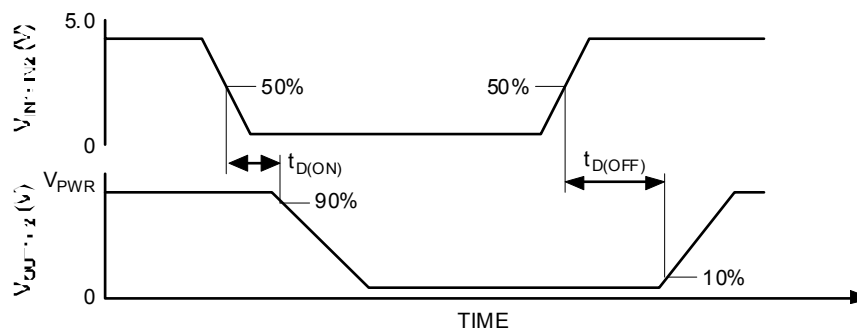


Figure 6. Output Delay Time

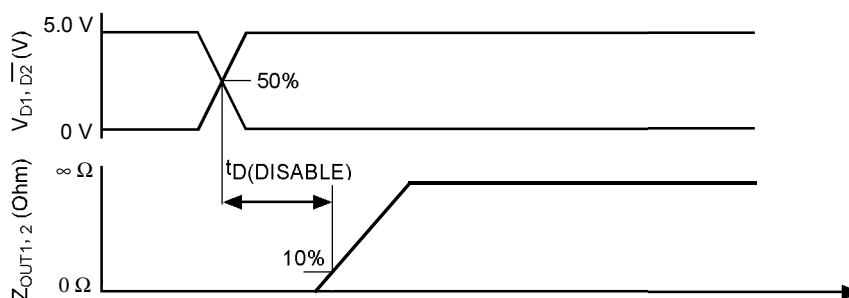


Figure 7. Disable Delay Time



Figure 8. Output Switching Time

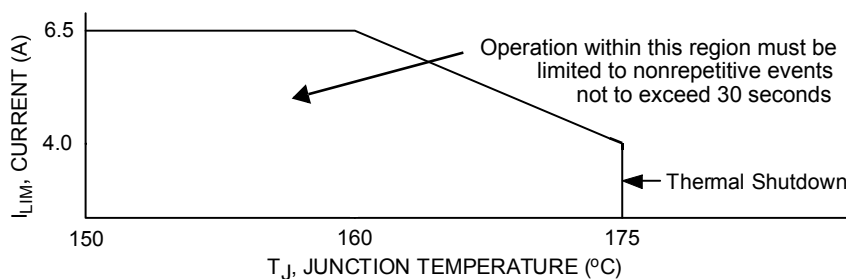


Figure 9. Active Current Limiting Versus Temperature (Typical)

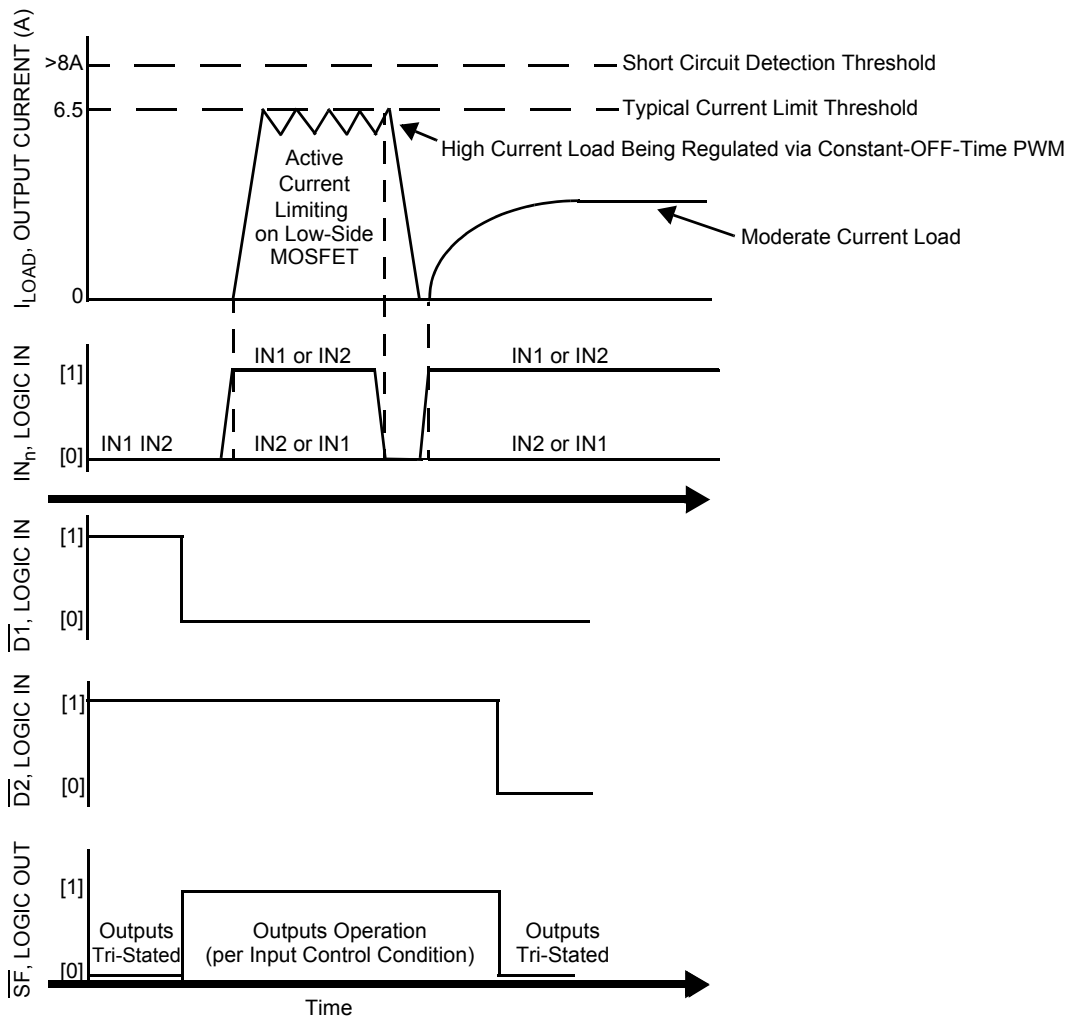


Figure 10. Operating States

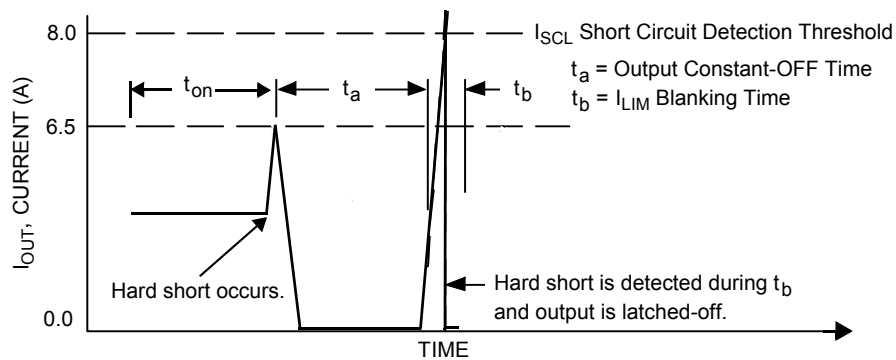
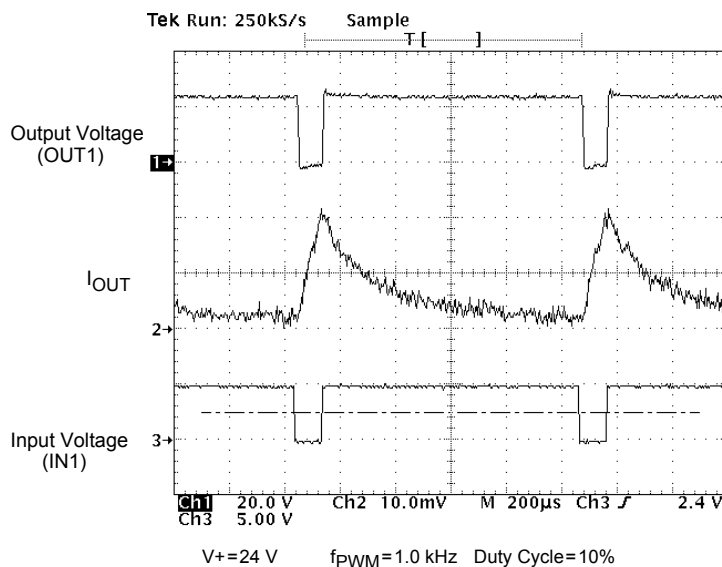


Figure 11. Example Short Circuit Detection Detail on Low-Side MOSFET

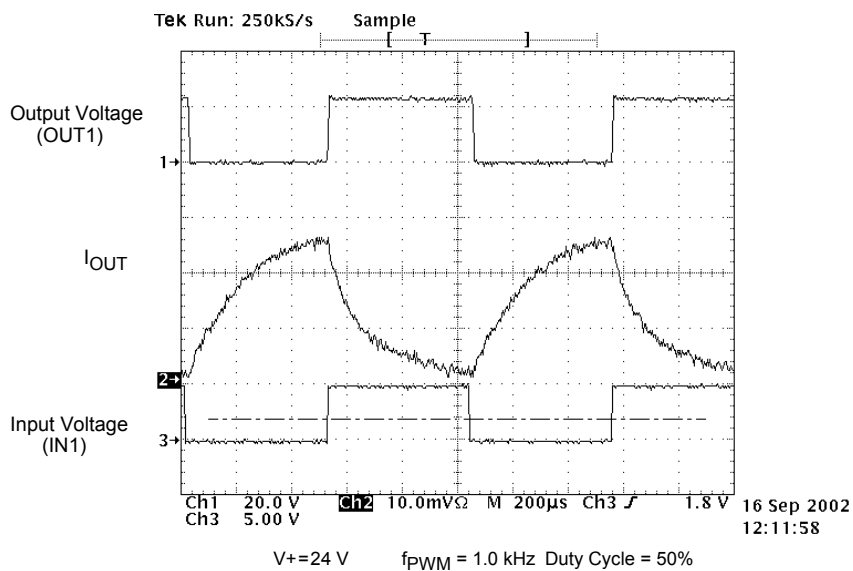
## TYPICAL SWITCHING WAVEFORMS

- Important** For all plots, the following applies:
- Ch2=2.0 A per division

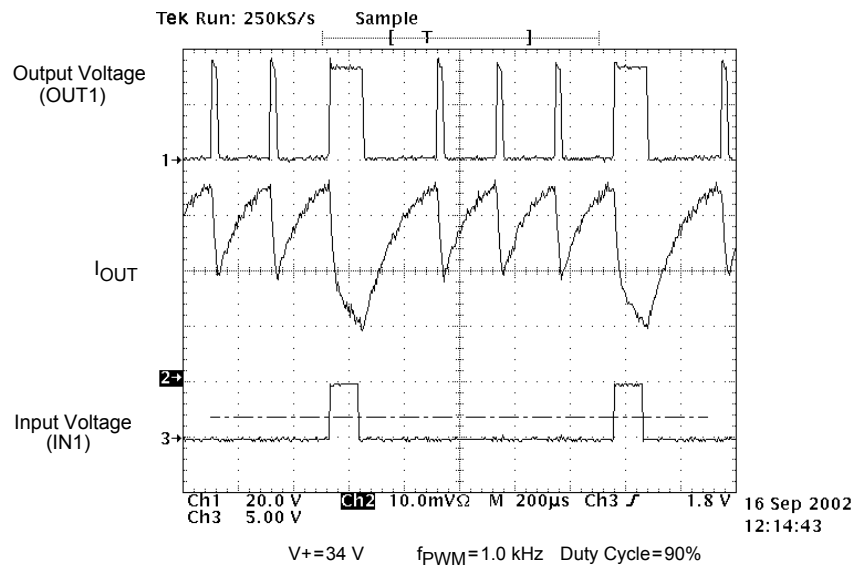
- $L_{LOAD}=533\ \mu\text{H}$  @ 1.0 kHz
- $L_{LOAD}=530\ \mu\text{H}$  @ 10.0 kHz
- $R_{LOAD}=4.0\ \Omega$



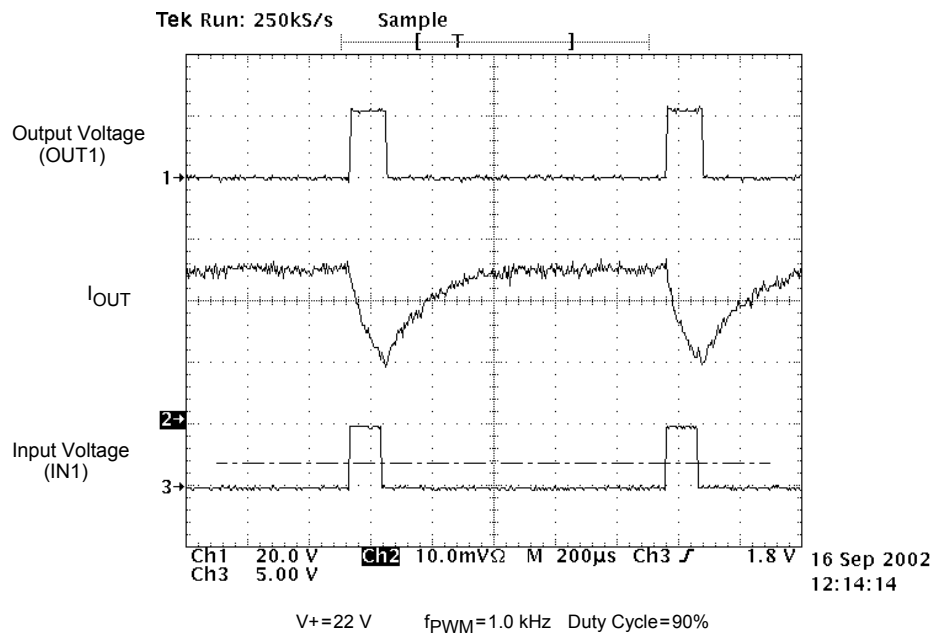
**Figure 12. Output Voltage and Current vs. Input Voltage at V+ = 24 V, PWM Frequency of 1.0 kHz, and Duty Cycle of 10%**



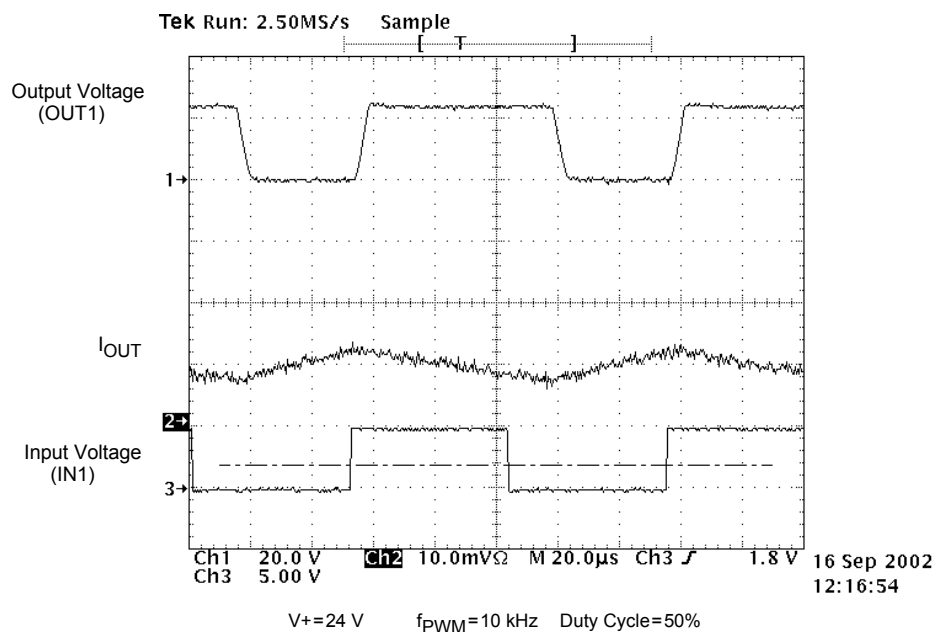
**Figure 13. Output Voltage and Current vs. Input Voltage at V+ = 24 V, PWM Frequency of 1.0 kHz, and Duty Cycle of 50%**



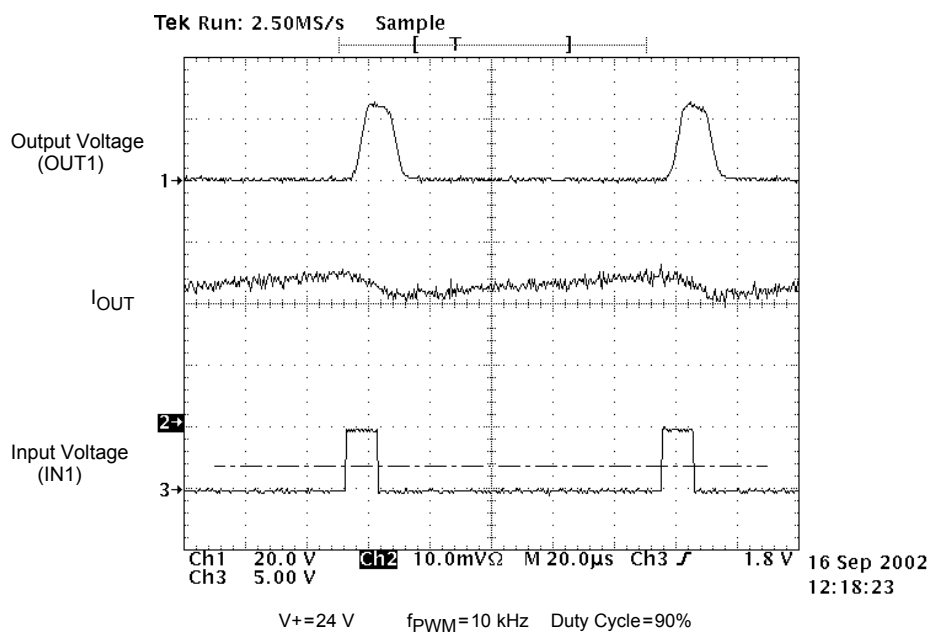
**Figure 14. Output Voltage and Current vs. Input Voltage at  $V+ = 34$  V, PMW Frequency of 1.0 kHz, and Duty Cycle of 90%, Showing Device in Current Limiting Mode**



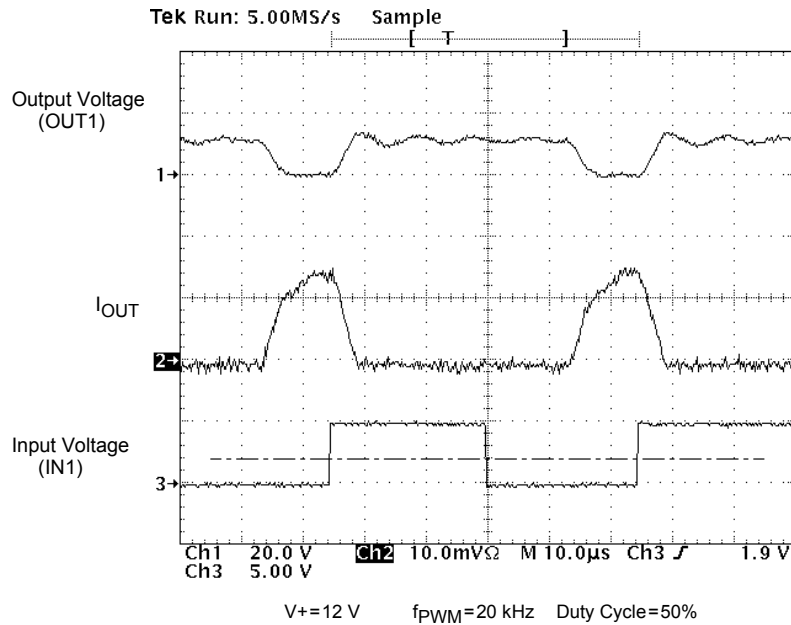
**Figure 15. Output Voltage and Current vs. Input Voltage at  $V+ = 22$  V, PMW Frequency of 1.0 kHz, and Duty Cycle of 90%**



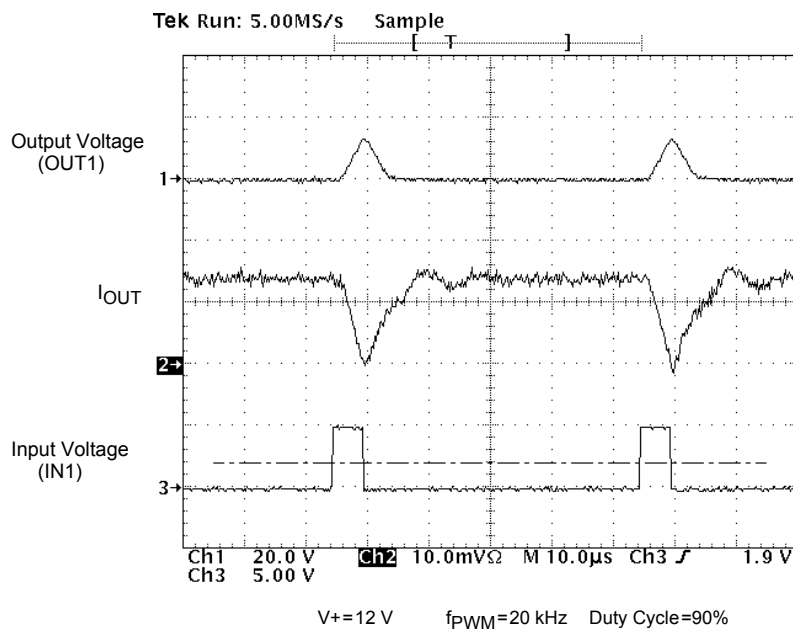
**Figure 16. Output Voltage and Current vs. Input Voltage at  $V+ = 24\text{ V}$ , PMW Frequency of 10 kHz, and Duty Cycle of 50%**



**Figure 17. Output Voltage and Current vs. Input Voltage at  $V+ = 24\text{ V}$ , PMW Frequency of 10 kHz, and Duty Cycle of 90%**

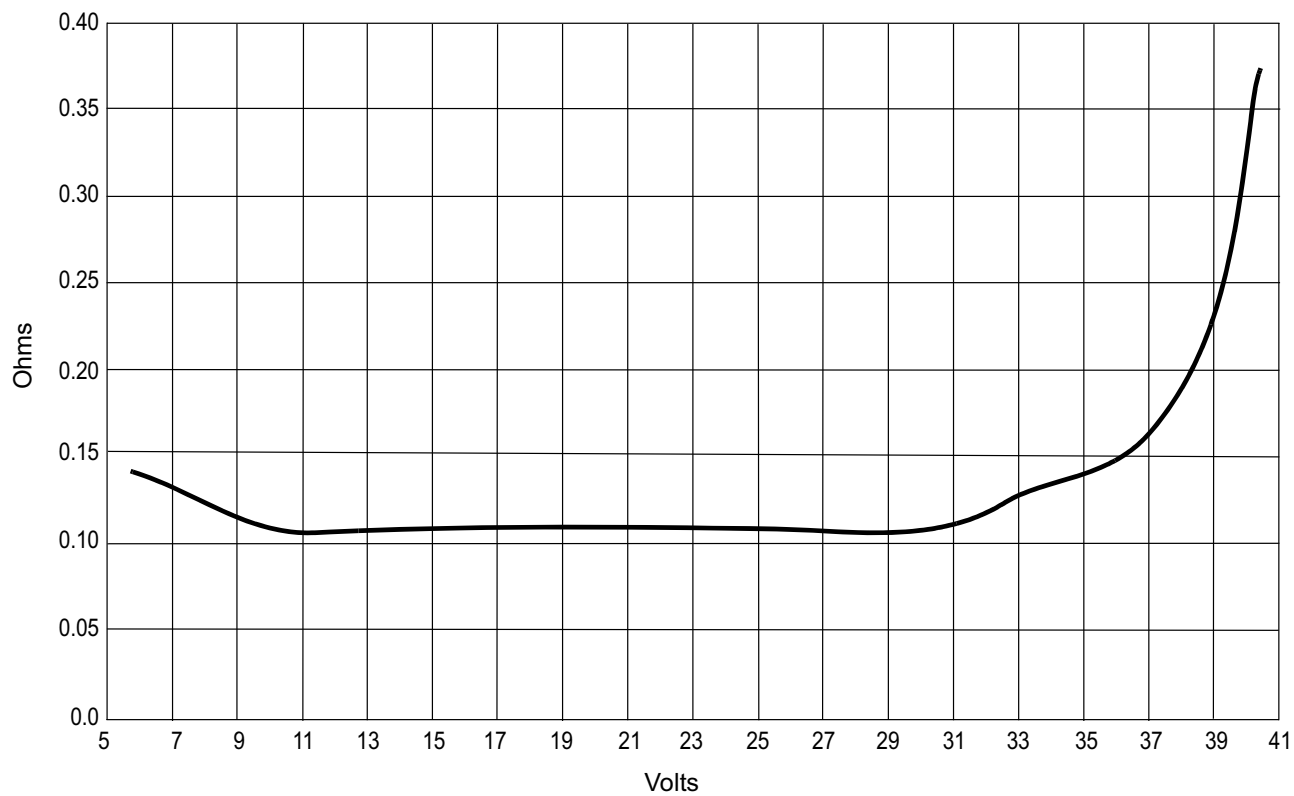


**Figure 18. Output Voltage and Current vs. Input Voltage at  $V_+ = 12\text{ V}$ , PMW Frequency of 20 kHz, and Duty Cycle of 50% for a Purely Resistive Load**

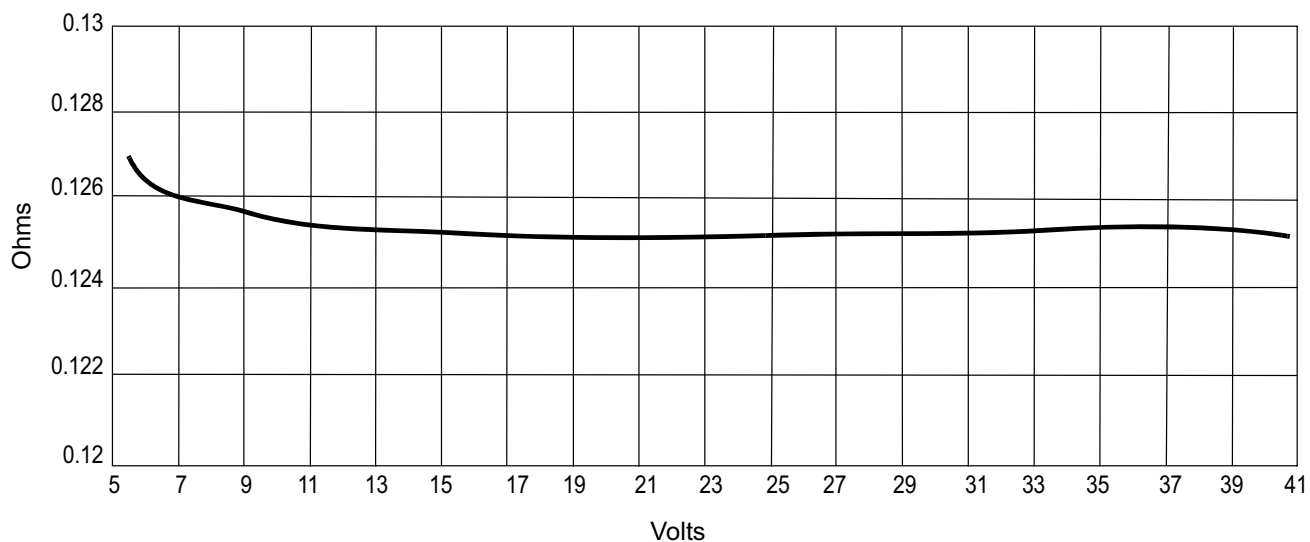


**Figure 19. Output Voltage and Current vs. Input Voltage at  $V_+ = 12\text{ V}$ , PMW Frequency of 20 kHz, and Duty Cycle of 90% for a Purely Resistive Load**

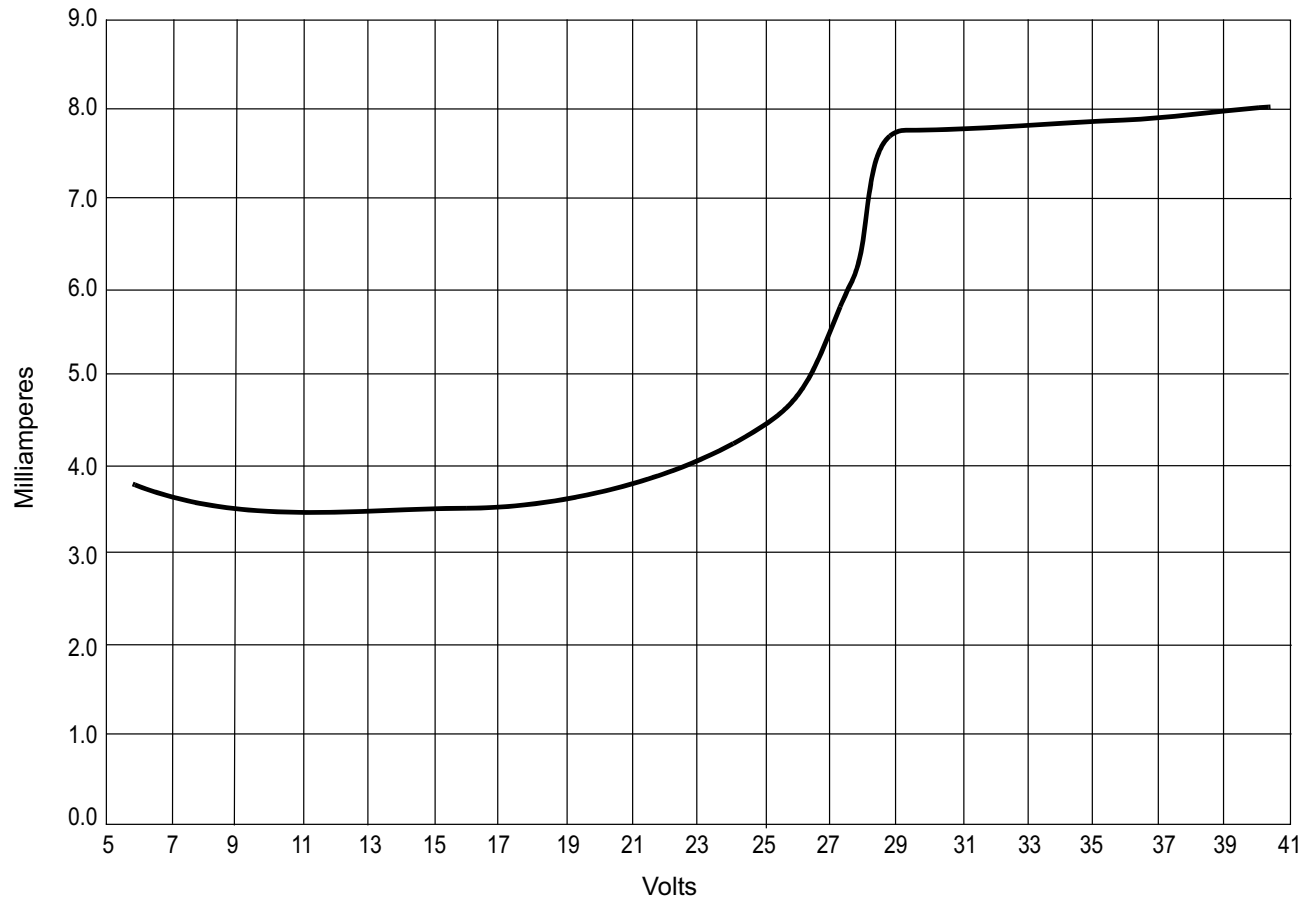
**ELECTRICAL PERFORMANCE CURVES**



**Figure 20. Typical High-Side  $R_{DS(ON)}$  Versus  $V+$**



**Figure 21. Typical Low-Side  $R_{DS(ON)}$  Versus  $V+$**



**Figure 22. Typical Quiescent Supply Current Versus V+**

**Table 6. Truth Table**

The tri-state conditions and the fault status are reset using D1 or  $\overline{D2}$ . The truth table uses the following notations: L = LOW, H = HIGH, X = HIGH or LOW, and Z = High impedance (all output power transistors are switched off).

| Device State                    | Input Conditions |    |                 |     |     | Fault Status Flag | Output States |      |
|---------------------------------|------------------|----|-----------------|-----|-----|-------------------|---------------|------|
|                                 | EN               | D1 | $\overline{D2}$ | IN1 | IN2 |                   | OUT1          | OUT2 |
| Forward                         | H                | L  | H               | H   | L   | H                 | H             | L    |
| Reverse                         | H                | L  | H               | L   | H   | H                 | L             | H    |
| Freewheeling Low                | H                | L  | H               | L   | L   | H                 | L             | L    |
| Freewheeling High               | H                | L  | H               | H   | H   | H                 | H             | H    |
| Disable 1 (D1)                  | H                | H  | X               | X   | X   | L                 | Z             | Z    |
| Disable 2 ( $\overline{D2}$ )   | H                | X  | L               | X   | X   | L                 | Z             | Z    |
| IN1 Disconnected                | H                | L  | H               | Z   | X   | H                 | H             | X    |
| IN2 Disconnected                | H                | L  | H               | X   | Z   | H                 | X             | H    |
| D1 Disconnected                 | H                | Z  | X               | X   | X   | L                 | Z             | Z    |
| $\overline{D2}$ Disconnected    | H                | X  | Z               | X   | X   | L                 | Z             | Z    |
| Undervoltage <sup>(34)</sup>    | H                | X  | X               | X   | X   | L                 | Z             | Z    |
| Overtemperature <sup>(35)</sup> | H                | X  | X               | X   | X   | L                 | Z             | Z    |
| Short Circuit <sup>(35)</sup>   | H                | X  | X               | X   | X   | L                 | Z             | Z    |
| Sleep Mode EN                   | L                | X  | X               | X   | X   | H                 | Z             | Z    |
| EN Disconnected                 | Z                | X  | X               | X   | X   | H                 | Z             | Z    |

**Notes**

- 34 In the case of an undervoltage condition, the outputs tri-state and the fault status is SET logic LOW. Upon undervoltage recovery, fault status is reset automatically or automatically cleared and the outputs are restored to their original operating condition.
- 35 When a short circuit or overtemperature condition is detected, the power outputs are tri-state latched-OFF independent of the input signals and the fault status flag is SET logic LOW.

## FUNCTIONAL DESCRIPTION

### INTRODUCTION

Numerous protection and operational features (speed, torque, direction, dynamic braking, PWM control, and closed-loop control), in addition to the 5.0 A current capability, make the 33887 a very attractive, cost-effective solution for controlling a broad range of small DC motors. In addition, a

pair of 33887 devices can be used to control bipolar stepper motors. The 33887 can also be used to excite transformer primary windings with a switched square wave to produce secondary winding AC currents.

### FUNCTIONAL PIN DESCRIPTIONS

#### POWER GROUND AND ANALOG GROUND (PGND AND AGND)

Power and analog ground pins should be connected together with a very low impedance connection.

#### POSITIVE POWER SUPPLY (V+)

V+ pins are the power supply inputs to the device. All V+ pins must be connected together on the printed circuit board with as short as possible traces offering as low impedance as possible between pins.

V+ pins have an undervoltage threshold. If the supply voltage drops below a V+ undervoltage threshold, the output power stage switches to a tri-state condition and the fault status flag is SET and the Fault Status pin voltage switched to a logic LOW. When the supply voltage returns to a level that is above the threshold, the power stage automatically resumes normal operation according to the established condition of the input pins and the fault status flag is automatically reset logic HIGH.

As V+ increases in value above 28 V, the charge pump performance begins to degrade. At +40 V, the charge pump is effectively non-functional. Operation at this high voltage level will result in the output FETs not being enhanced when turned on. This means that the voltage on the output will be  $V_{OUT} = (V+) - V_{GS}$ . This increased voltage drop under load will produce a higher power dissipation.

#### FAULT STATUS ( $\overline{FS}$ )

The  $\overline{FS}$  pin is the device fault status output. This output is an active LOW open drain structure requiring a pull-up resistor to 5.0 V. Refer to [Table 6, Truth Table](#), page 20.

#### LOGIC INPUT CONTROL AND DISABLE (IN1, IN2, D1, AND $\overline{D2}$ )

These pins are input control pins used to control the outputs. These pins are 5.0 V CMOS-compatible inputs with hysteresis. The IN1 and IN2 independently control OUT1 and OUT2, respectively. D1 and  $\overline{D2}$  are complementary inputs used to tri-state disable the H-Bridge outputs.

When either D1 or  $\overline{D2}$  is SET (D1 = logic HIGH or  $\overline{D2}$  = logic LOW) in the disable state, outputs OUT1 and OUT2 are both tri-state disabled; however, the rest of the circuitry is fully operational and the supply  $I_{Q(standby)}$  current is reduced to a

few milliamperes. Refer to [Table 6, Truth Table](#), and [STATIC ELECTRICAL CHARACTERISTICS](#) table, page 9.

#### H-BRIDGE OUTPUT (OUT1 AND OUT2)

These pins are the outputs of the H-Bridge with integrated output MOSFET body diodes. The bridge output is controlled using the IN1, IN2, D1, and  $\overline{D2}$  inputs. The low-side MOSFETs have active current limiting above the  $I_{LIM}$  threshold. The outputs also have thermal shutdown (tri-state latch-OFF) with hysteresis as well as short circuit latch-OFF protection.

A disable timer (time  $t_b$ ) USED to detect currents that are higher than current limit is activated at each output activation to facilitate hard short detection (see [Figure 11](#), page 13).

#### Charge Pump Capacitor (CCP)

A filter capacitor (up to 33 nF) can be connected from the charge pump output pin and PGND. The device can operate without the external capacitor, although the  $C_{CP}$  capacitor helps to reduce noise and allows the device to perform at maximum speed, timing, and PWM frequency.

#### ENABLE (EN)

The EN pin is used to place the device in a sleep mode so as to consume very low currents. When the EN pin voltage is a logic LOW state, the device is in the sleep mode. The device is enabled and fully operational when the EN pin voltage is logic HIGH. An internal pull-down resistor maintains the device in sleep mode in the event EN is driven through a high impedance I/O or an unpowered microcontroller, or the EN input becomes disconnected.

#### FEEDBACK FOR H-BRIDGE (FB)

The 33887 has a feedback output (FB) for "real time" monitoring of H-Bridge high-side current to facilitate closed-loop operation for motor speed and torque control.

The FB pin provides current sensing feedback of the H-Bridge high-side drivers. When running in forward or reverse direction, a ground referenced 1/375th (0.00266) of load current is output to this pin. Through an external resistor to ground, the proportional feedback current can be converted to a proportional voltage equivalent and the controlling microcontroller can "read" the current proportional

voltage with its analog-to-digital converter (ADC). This is intended to provide the user with motor current feedback for motor torque control. The resistance range for the linear operation of the FB pin is  $100 < R_{FB} < 200 \, \Omega$ .

If PWM-ing is implemented using the disable pin inputs (either D1 or  $\overline{D2}$ ), a small filter capacitor ( $1.0 \, \mu\text{F}$  or less) may be required in parallel with the external resistor to ground for fast spike suppression.

## FUNCTIONAL DEVICE OPERATION

### OPERATIONAL MODES

The 33887 Simplified Internal Block Diagram shown in [Figure 2](#), page 2, is a fully protected monolithic H-Bridge with Enable, Fault Status reporting, and High-Side current sense feedback to accommodate closed-loop PWM control. For a DC motor to run, the input conditions need be as follows: Enable input logic HIGH, D1 input logic LOW, D2 input logic HIGH,  $\overline{FS}$  flag cleared (logic HIGH), one IN logic LOW and the other IN logic HIGH (to define output polarity). The 33887 can execute dynamic braking by simultaneously turning on either both high-side MOSFETs or both low-side MOSFETs in the output H-Bridge; e.g., IN1 and IN2 logic HIGH or IN1 and IN2 logic LOW.

The 33887 outputs are capable of providing a continuous DC load current of 5.0 A from a 28 V V+ source. An internal charge pump supports PWM frequencies to 10 kHz. An external pull-up resistor is required at the  $\overline{FS}$  pin for fault status reporting. The 33887 has an analog feedback (current mirror) output pin (the FB pin) that provides a constant-current source ratioed to the active high-side MOSFET. This can be used to provide “real time” monitoring of load current to facilitate closed-loop operation for motor speed/torque control.

Two independent inputs (IN1 and IN2) provide control of the two totem-pole half-bridge outputs. Two disable inputs

(D1 and  $\overline{D2}$ ) provide the means to force the H-Bridge outputs to a high-impedance state (all H-Bridge switches OFF). An EN pin controls an enable function that allows the 33887 to be placed in a power-conserving sleep mode.

The 33887 has undervoltage shutdown with automatic recovery, active current limiting, output short-circuit latch-OFF, and overtemperature latch-OFF. An undervoltage shutdown, output short-circuit latch-OFF, or overtemperature latch-OFF fault condition will cause the outputs to turn OFF (i.e., become high impedance or tri-stated) and the fault output flag to be set LOW. Either of the Disable inputs or V+ must be “toggled” to clear the fault flag.

Active current limiting is accomplished by a constant OFF-time PWM method employing active current limiting threshold triggering. The active current limiting scheme is unique in that it incorporates a junction temperature-dependent current limit threshold. This means the active current limiting threshold is “ramped down” as the junction temperature increases above 160°C, until at 175°C the current will have been decreased to about 4.0 A. Above 175°C, the overtemperature shutdown (latch-OFF) occurs. This combination of features allows the device to remain in operation for 30 seconds at junction temperatures above 150°C for nonrepetitive unexpected loads.

## PROTECTION AND DIAGNOSTIC FEATURES

### SHORT CIRCUIT PROTECTION

If an output short circuit condition is detected, the power outputs tri-state (latch-OFF) independent of the input (IN1 and IN2) states, and the fault status output flag is SET logic LOW. If the D1 input changes from logic HIGH to logic LOW, or if the D2 input changes from logic LOW to logic HIGH, the output bridge will become operational again and the fault status flag will be reset (cleared) to a logic HIGH state.

The output stage will always switch into the mode defined by the input pins (IN1, IN2, D1, and  $\overline{D2}$ ), provided the device junction temperature is within the specified operating temperature range.

### ACTIVE CURRENT LIMITING

The maximum current flow under normal operating conditions is internally limited to  $I_{LIM}$  (5.2 A to 7.8 A). When the maximum current value is reached, the output stages are tri-stated for a fixed time ( $t_a$ ) of 20  $\mu$ s typical. Depending on the time constant associated with the load characteristics, the current decreases during the tri-state duration until the next output ON cycle occurs (see [Figures 11](#) and [14](#), page [13](#) and page [15](#), respectively).

The current limiting threshold value is dependent upon the device junction temperature. When  $-40^{\circ}\text{C} \leq T_J \leq 160^{\circ}\text{C}$ ,  $I_{LIM}$  is between 5.2 A to 7.8 A. When  $T_J$  exceeds  $160^{\circ}\text{C}$ , the  $I_{LIM}$  current decreases linearly down to 4.0 A typical at  $175^{\circ}\text{C}$ . Above  $175^{\circ}\text{C}$  the device overtemperature circuit detects  $T_{LIM}$

and overtemperature shutdown occurs (see [Figure 9](#), page [12](#)). This feature allows the device to remain operational for a longer time but at a regressing output performance level at junction temperatures above  $160^{\circ}\text{C}$ .

### Output Avalanche Protection

An inductive fly-back event, namely when the outputs are suddenly disabled and V+ is lost, could result in electrical overstress of the drivers. To prevent this the V+ input to the 33887 should not exceed the maximum rating during a fly-back condition. This may be done with either a zener clamp and/or an appropriately valued input capacitor with sufficiently low ESR.

### OVERTEMPERATURE SHUTDOWN AND HYSTERESIS

If an overtemperature condition occurs, the power outputs are tri-stated (latched-OFF) and the fault status flag is SET to logic LOW.

To reset from this condition, D1 must change from logic HIGH to logic LOW, or  $\overline{D2}$  must change from logic LOW to logic HIGH. When reset, the output stage switches ON again, provided that the junction temperature is now below the overtemperature threshold limit minus the hysteresis.

**Note** Resetting from the fault condition will clear the fault status flag.

## TYPICAL APPLICATIONS

Figure 23 shows a typical application schematic. For precision high-current applications in harsh, noisy environments, the V+ by-pass capacitor may need to be substantially larger.

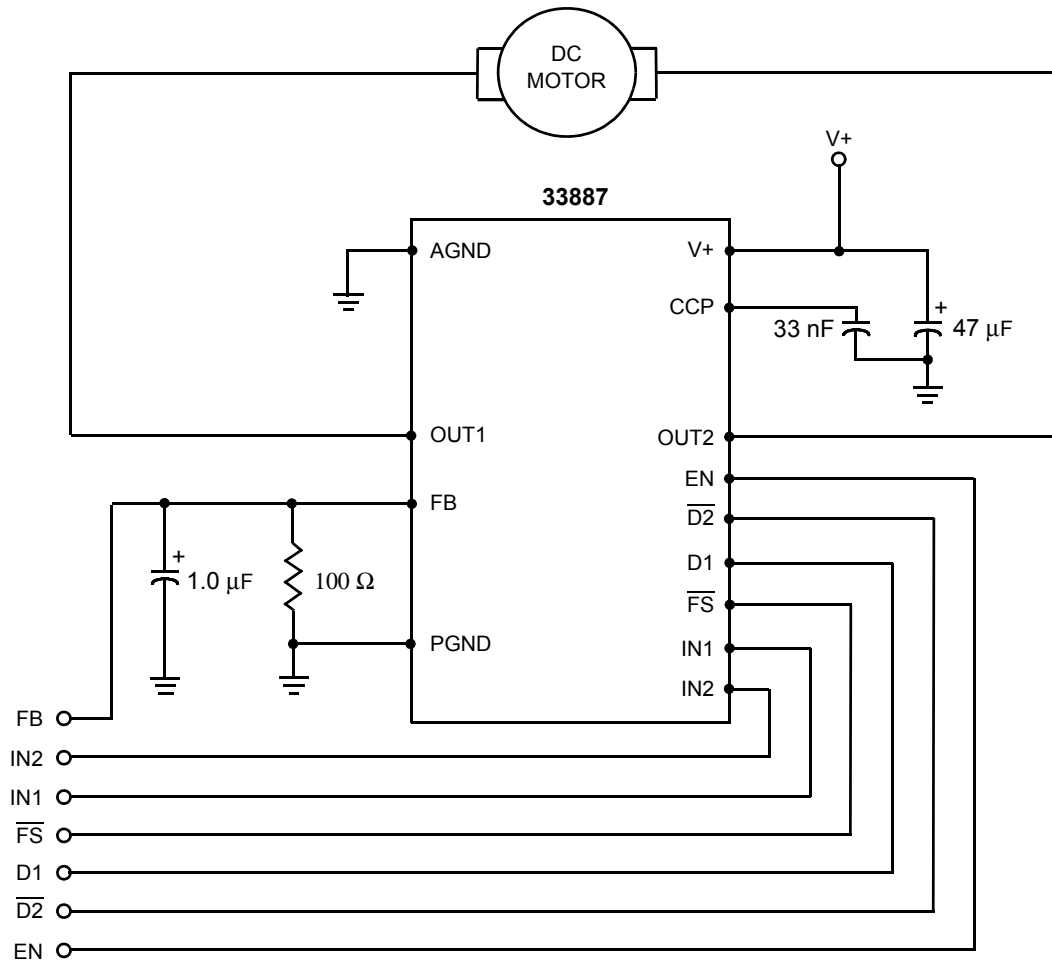


Figure 23. 33887 Typical Application Schematic

## PACKAGING

### SOLDERING INFORMATION

The 33887 packages are designed for thermal performance. The significant feature of these packages is the exposed pad on which the power die is soldered. When soldered to a PCB, this pad provides a path for heat flow to the ambient environment. The more copper area and thickness on the PCB, the better the power dissipation and transient behavior will be.

**Example** Characterization on a double-sided PCB: bottom side area of copper is 7.8 cm<sup>2</sup>; top surface is 2.7 cm<sup>2</sup> (see [Figure](#)); grid array of 24 vias 0.3 mm in diameter

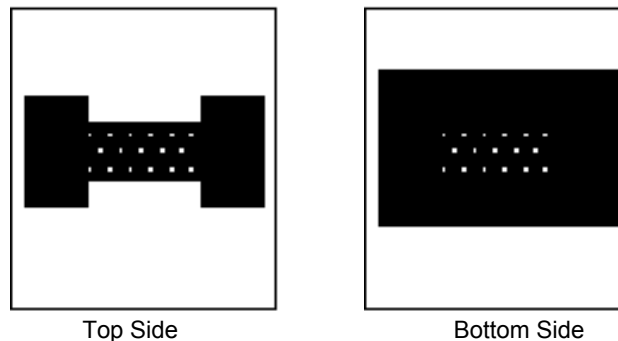
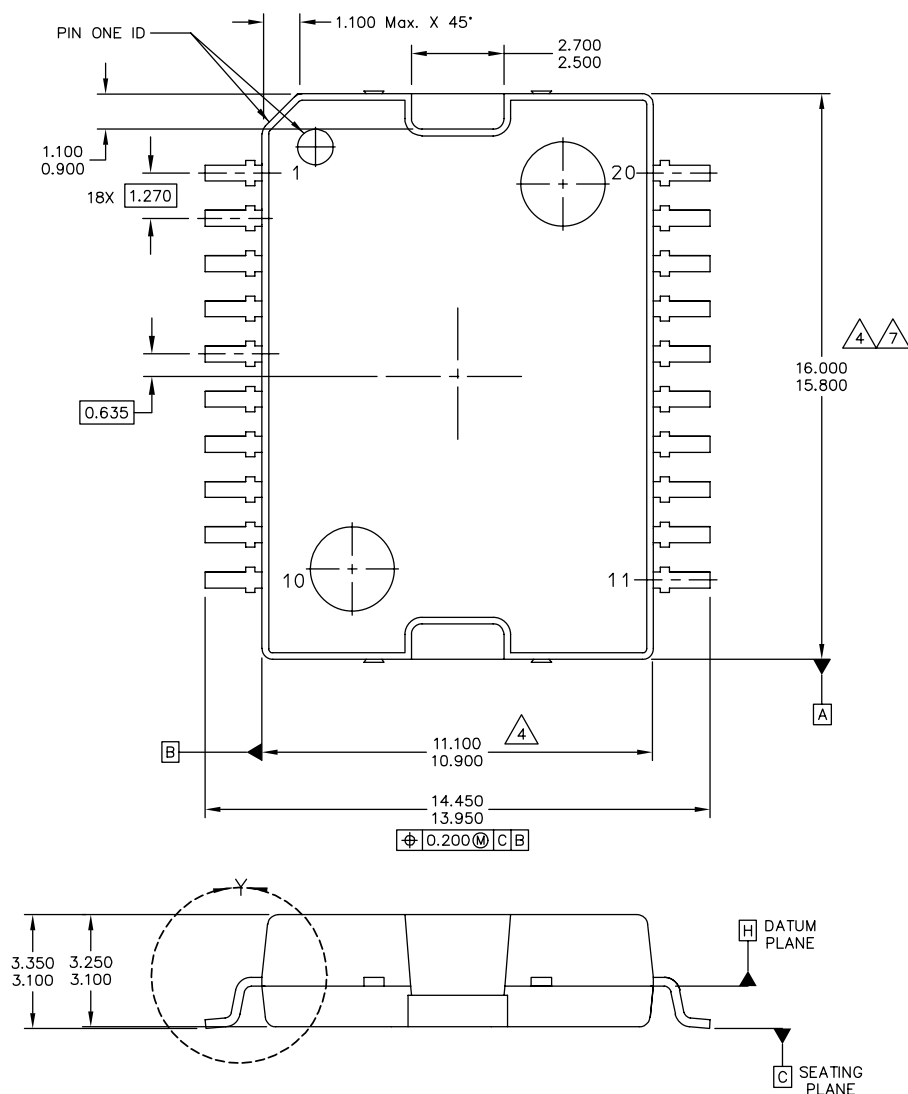


Figure 24. PCB Test Layout

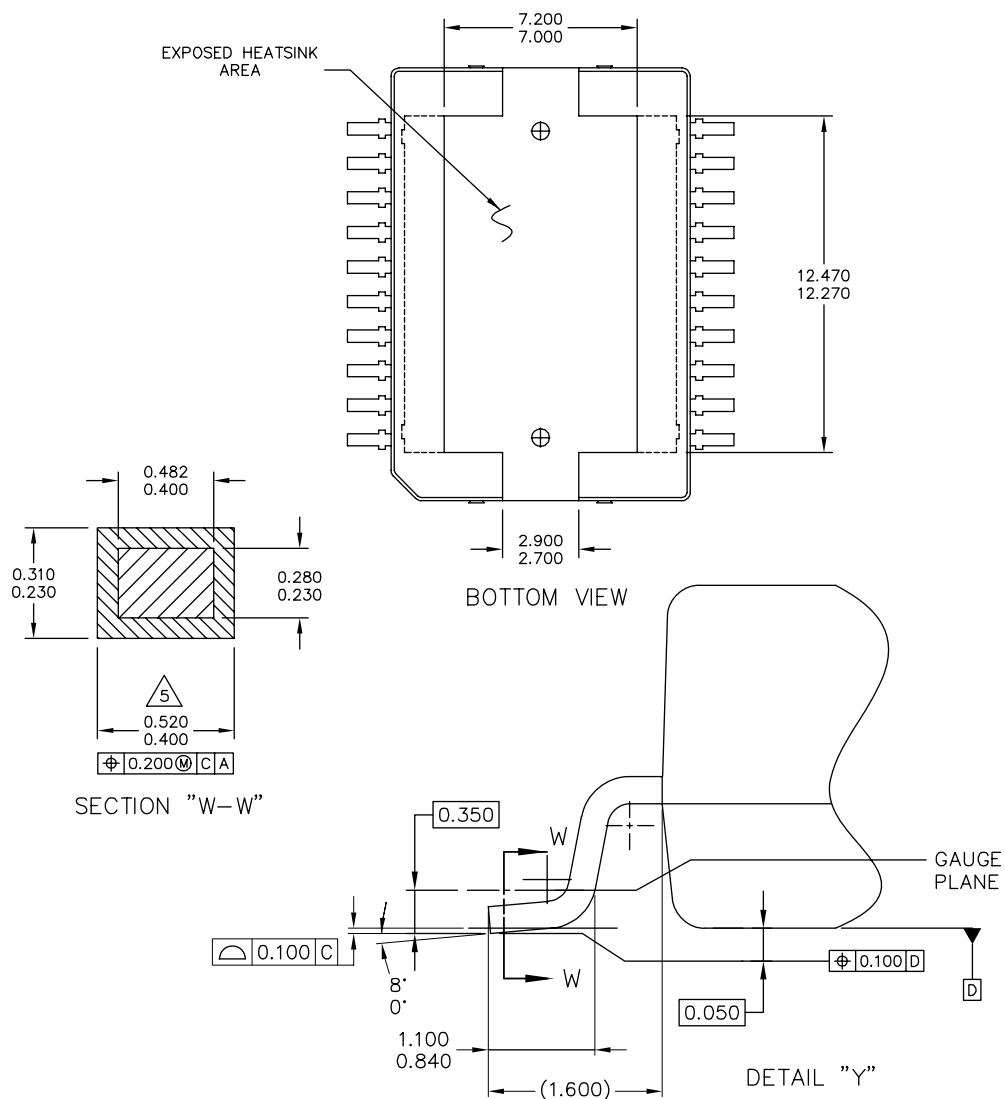
# PACKAGING DIMENSIONS

**Important** For the most current revision of the package, visit [www.freescale.com](http://www.freescale.com) and perform a keyword search on the 98A drawing number below



|                                                         |                           |                            |             |
|---------------------------------------------------------|---------------------------|----------------------------|-------------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. | <b>MECHANICAL OUTLINE</b> | PRINT VERSION NOT TO SCALE |             |
| TITLE:<br><br>20 LEAD HSOP                              | DOCUMENT NO: 98ASH70273A  |                            | REV: E      |
|                                                         | CASE NUMBER: 979-04       |                            | 19 MAY 2005 |
|                                                         | STANDARD: NON-JEDEC       |                            |             |

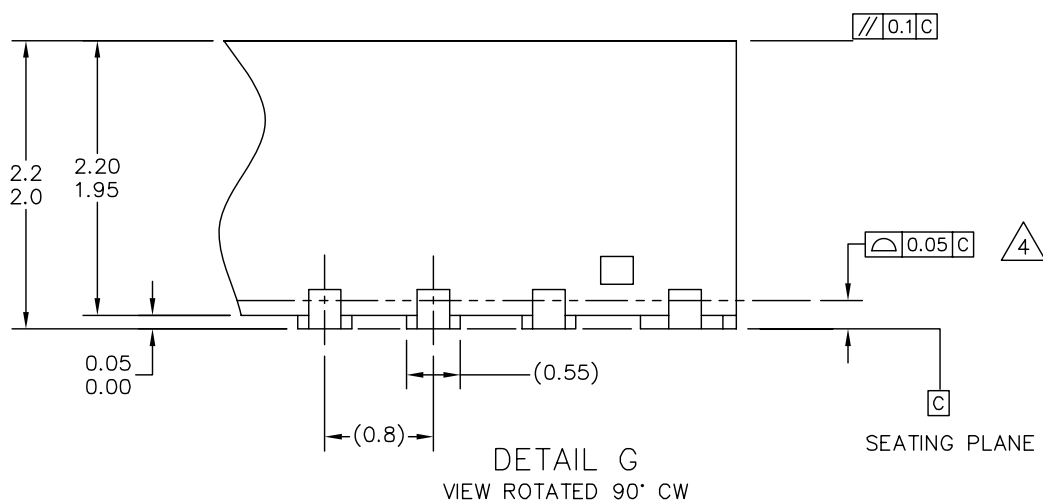
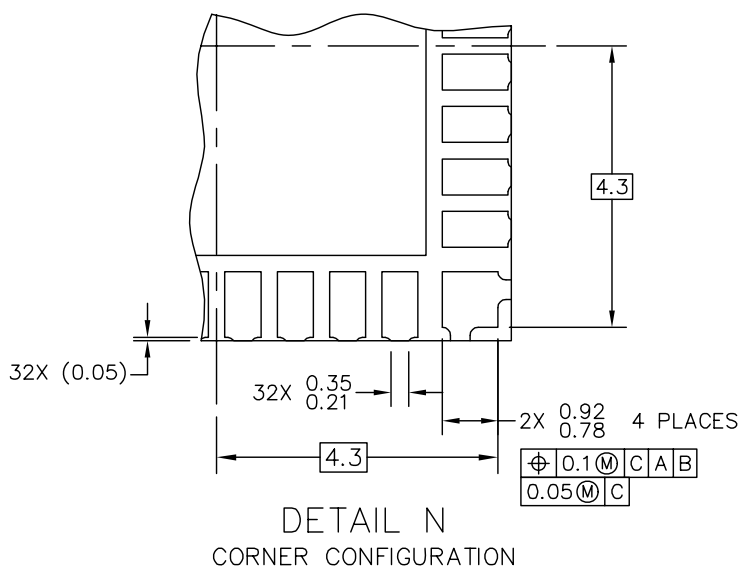
**DH SUFFIX**  
**VW SUFFIX**  
20-PIN HSOP  
PLASTIC PACKAGE  
98ASH70273A  
ISSUE E



|                                                         |  |                          |  |                            |  |
|---------------------------------------------------------|--|--------------------------|--|----------------------------|--|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. |  | MECHANICAL OUTLINE       |  | PRINT VERSION NOT TO SCALE |  |
| TITLE:<br><br>20 LEAD HSOP                              |  | DOCUMENT NO: 98ASH70273A |  | REV: E                     |  |
|                                                         |  | CASE NUMBER: 979—04      |  | 19 MAY 2005                |  |
|                                                         |  | STANDARD: NON—JEDEC      |  |                            |  |

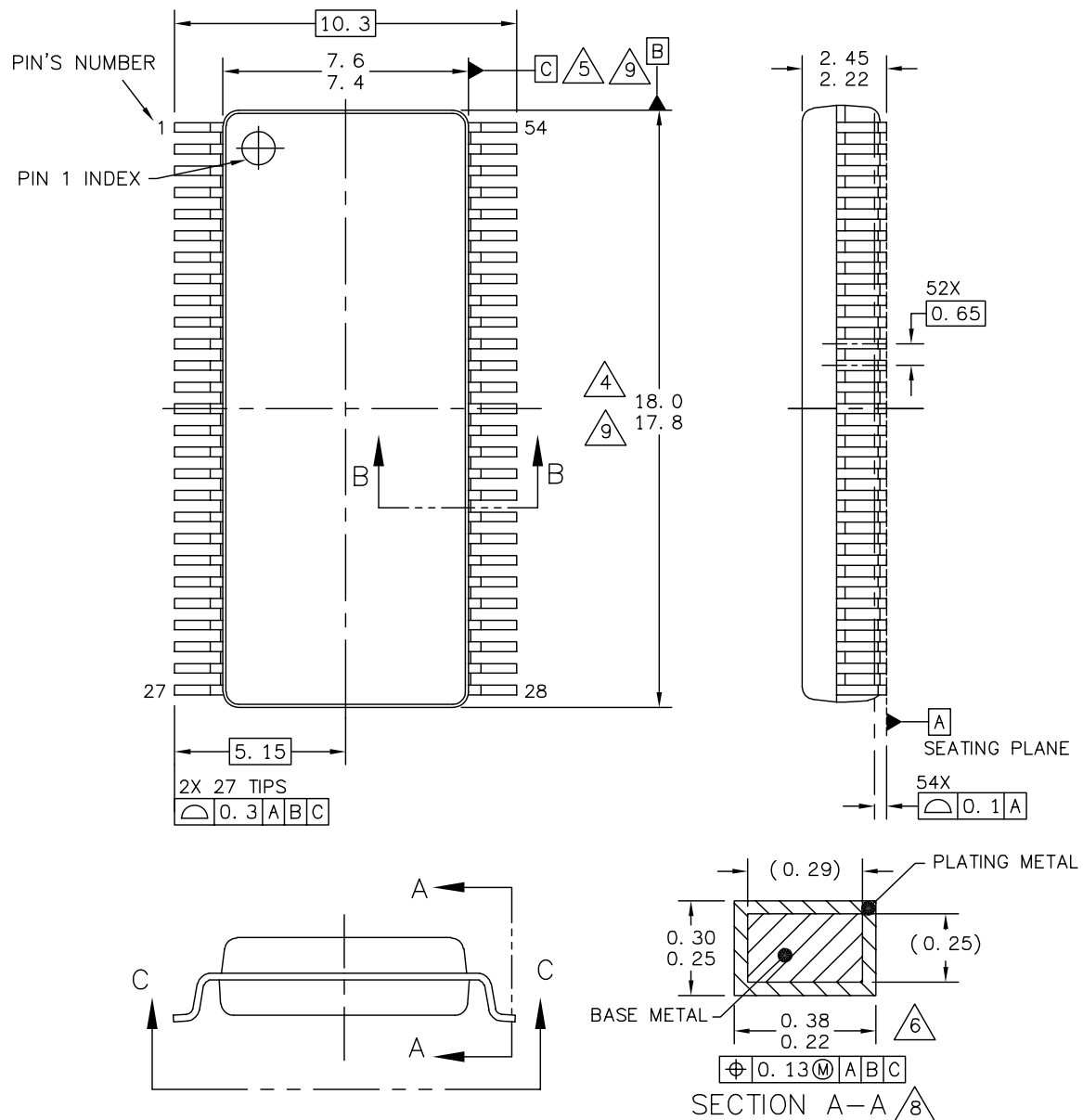
**DH SUFFIX**  
**VW SUFFIX**  
20-PIN HSOP  
PLASTIC PACKAGE  
98ASH70273A  
ISSUE E





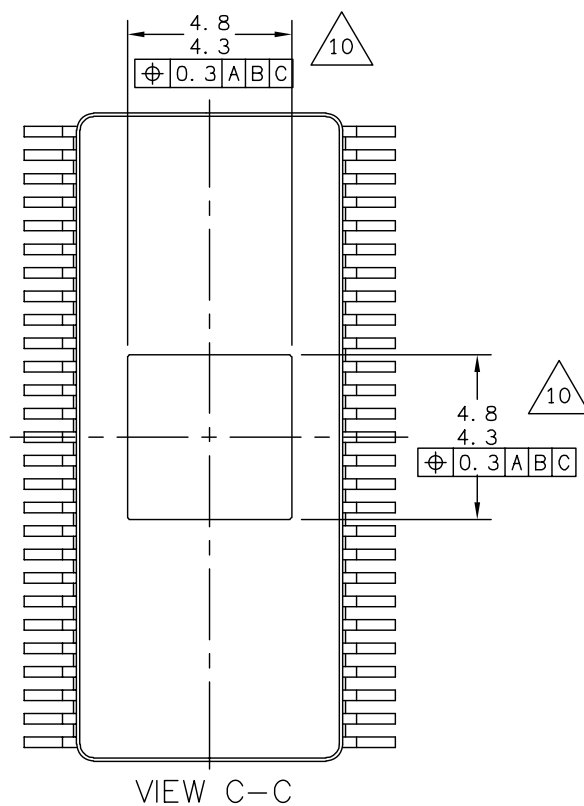
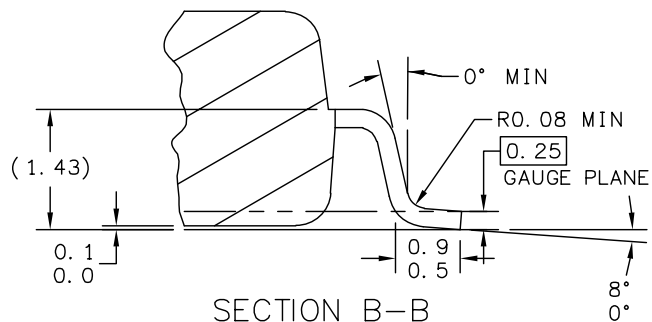
|                                                                                           |  |                                |  |                            |  |
|-------------------------------------------------------------------------------------------|--|--------------------------------|--|----------------------------|--|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED.                                   |  | <b>MECHANICAL OUTLINE</b>      |  | PRINT VERSION NOT TO SCALE |  |
| TITLE: POWER QUAD FLAT<br>NON-LEADED PACKAGE (PWR QFN),<br>36 TERMINAL 0.8 PITCH(9X9X2.1) |  | DOCUMENT NO: 98ASA10583D       |  | REV: C                     |  |
|                                                                                           |  | CASE NUMBER: 1503-04           |  | 14 JUL 2005                |  |
|                                                                                           |  | STANDARD: JEDEC MO-251A AEEB-1 |  |                            |  |

**PNB (Pb-FREE) SUFFIX**  
36-PIN PQFN  
Pb-Free PACKAGE  
98ASA10583D  
ISSUE C



|                                                                               |                           |                            |
|-------------------------------------------------------------------------------|---------------------------|----------------------------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED.                       | <b>MECHANICAL OUTLINE</b> | PRINT VERSION NOT TO SCALE |
| TITLE:<br>54LD SOIC W/B, 0.65 PITCH<br>4.6 X 4.6 EXPOSED PAD,<br>CASE-OUTLINE | DOCUMENT NO: 98ASA10506D  | REV: C                     |
|                                                                               | CASE NUMBER: 1390-02      | 11 MAR 2005                |
|                                                                               | STANDARD: NON-JEDEC       |                            |

**DWB SUFFIX**  
**EK SUFFIX (PB-FREE)**  
54-PIN SOICW EXPOSED PAD  
PLASTIC PACKAGE  
98ASA10506D  
ISSUE C



|                                                                               |                           |                            |             |
|-------------------------------------------------------------------------------|---------------------------|----------------------------|-------------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED.                       | <b>MECHANICAL OUTLINE</b> | PRINT VERSION NOT TO SCALE |             |
| TITLE:<br>54LD SOIC W/B, 0.65 PITCH<br>4.6 X 4.6 EXPOSED PAD,<br>CASE-OUTLINE | DOCUMENT NO: 98ASA10506D  |                            | REV: C      |
|                                                                               | CASE NUMBER: 1390-02      |                            | 11 MAR 2005 |
|                                                                               | STANDARD: NON-JEDEC       |                            |             |

**DWB SUFFIX**  
EK SUFFIX (PB-FREE)  
54-PIN SOICW EXPOSED PAD  
PLASTIC PACKAGE  
98ASA10506D  
ISSUE C

# ADDITIONAL DOCUMENTATION

## THERMAL ADDENDUM (REV 2.0)

### Introduction

This thermal addendum is provided as a supplement to the MC33887 technical data sheet. The addendum provides thermal performance information that may be critical in the design and development of system applications. All electrical, application, and packaging information is provided in the data sheet.

### Packaging and Thermal Considerations

The MC33887 is offered in a 20 pin HSOP exposed pad, single die package. There is a single heat source (P), a single junction temperature ( $T_J$ ), and thermal resistance ( $R_{\theta JA}$ ).

$$\{ T_J \} = [ R_{\theta JA} ] \cdot \{ P \}$$

The stated values are solely for a thermal performance comparison of one package to another in a standardized environment. This methodology is not meant to and will not predict the performance of a package in an application-specific environment. Stated values were obtained by measurement and simulation according to the standards listed below.

### Standards

Table 7. Thermal Performance Comparison

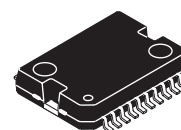
| Thermal Resistance       | [°C/W] |
|--------------------------|--------|
| $R_{\theta JA}$ (1),(2)  | 20     |
| $R_{\theta JB}$ (2),(3)  | 6.0    |
| $R_{\theta JA}$ (1), (4) | 52     |
| $R_{\theta JC}$ (5)      | 1.0    |

#### NOTES:

1. Per JEDEC JESD51-2 at natural convection, still air condition.
2. 2s2p thermal test board per JEDEC JESD51-5 and JESD51-7.
3. Per JEDEC JESD51-8, with the board temperature on the center trace near the center lead.
4. Single layer thermal test board per JEDEC JESD51-3 and JESD51-5.
5. Thermal resistance between the die junction and the exposed pad surface; cold plate attached to the package bottom side, remaining surfaces insulated

**33887DH**

**20-PIN  
HSOP-EP**



**DH SUFFIX  
98ASH70273A  
20-PIN HSOP-EP**

**Note** For package dimensions, refer to the 33887 device data sheet.

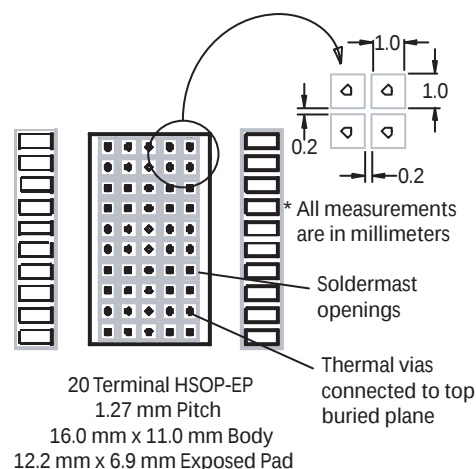


Figure 25. Thermal Land Pattern for Direct Thermal Attachment According to JESD51-5

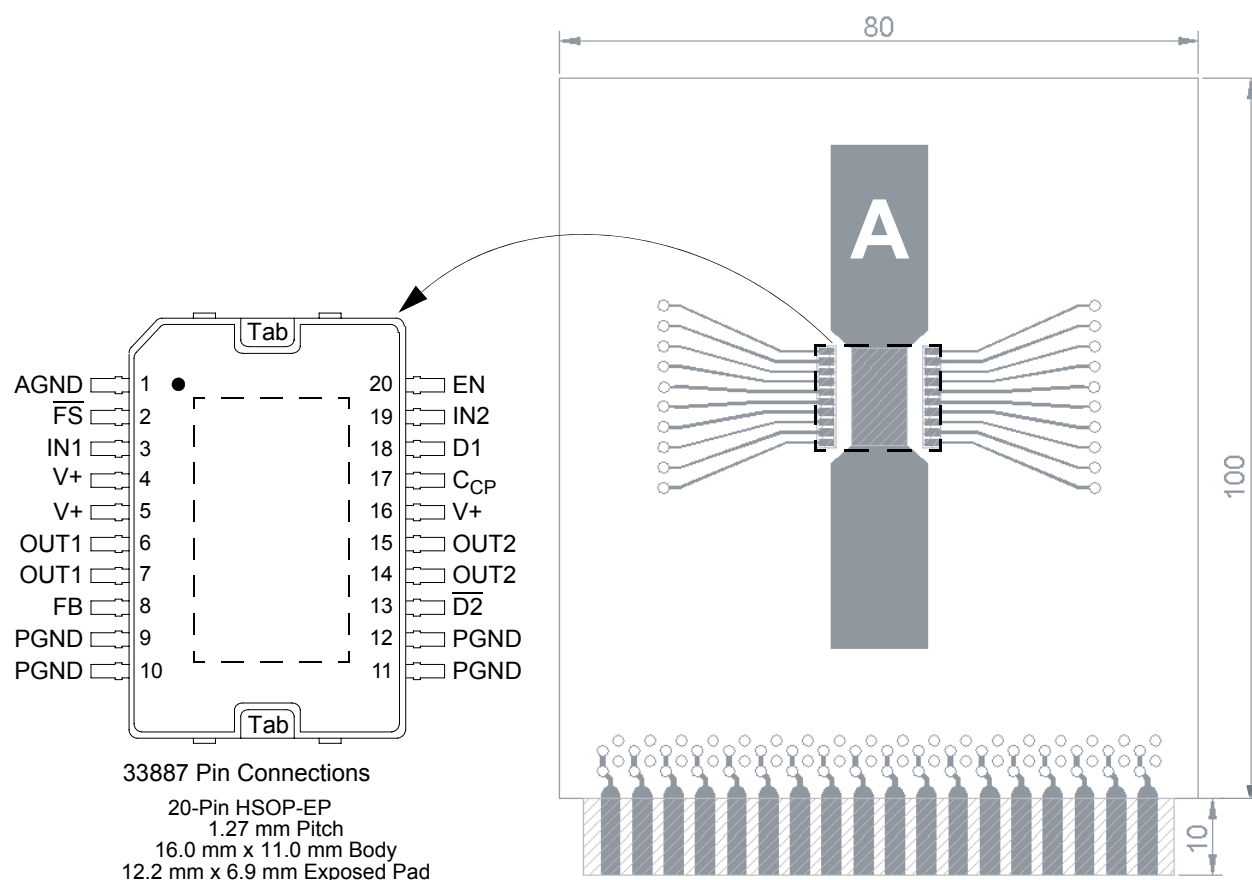


Figure 26. Thermal Test Board

#### Device on Thermal Test Board

|                     |                                                                                             |
|---------------------|---------------------------------------------------------------------------------------------|
| Material:           | Single layer printed circuit board<br>FR4, 1.6 mm thickness<br>Cu traces, 0.07 mm thickness |
| Outline:            | 80 mm x 100 mm board area,<br>including edge connector for thermal<br>testing               |
| Area A:             | Cu heat spreading areas on board<br>surface                                                 |
| Ambient Conditions: | Natural convection, still air                                                               |

Table 8. Thermal Resistance Performance

| Thermal Resistance | Area A (mm <sup>2</sup> ) | °C/W |
|--------------------|---------------------------|------|
| $R_{\theta JA}$    | 0.0                       | 52   |
|                    | 300                       | 36   |
|                    | 600                       | 32   |
| $R_{\theta JS}$    | 0.0                       | 10   |
|                    | 300                       | 7.0  |
|                    | 600                       | 6.0  |

$R_{\theta JA}$  is the thermal resistance between die junction and ambient air.

$R_{\theta JS}$  is the thermal resistance between die junction and the reference location on the board surface near a center lead of the package (see Figure 26).

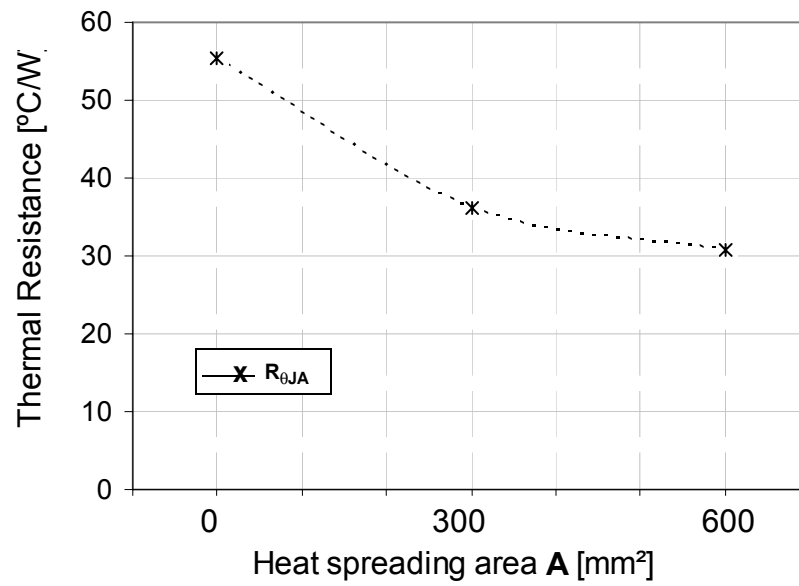


Figure 27. Device on Thermal Test Board  $R_{\theta JA}$

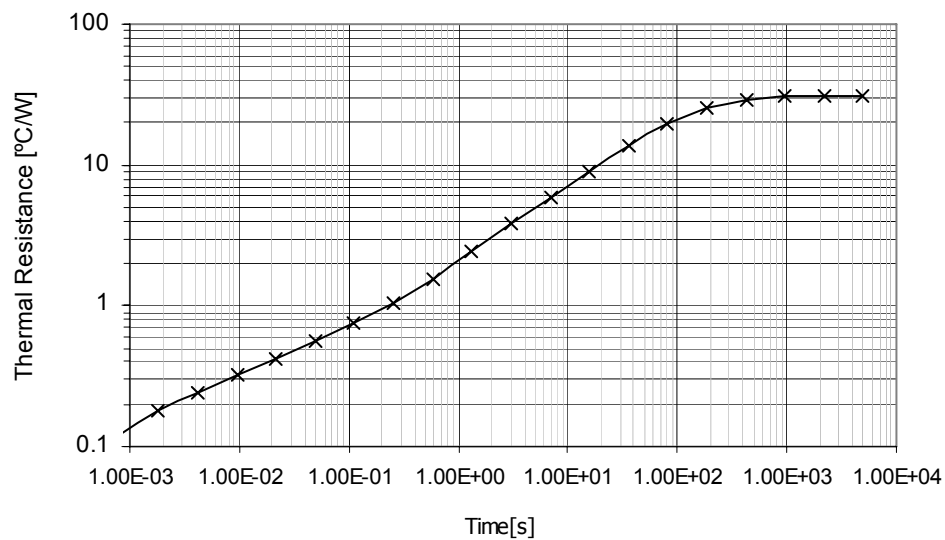


Figure 28. Transient Thermal Resistance  $R_{\theta JA}$   
Device on Thermal Test Board Area A = 600 (mm²)

## REVISION HISTORY

| REVISION | DATE    | DESCRIPTION                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
|----------|---------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 10.0     | 7/2005  | <ul style="list-style-type: none"> <li>Added Thermal Addendum &amp; Converted to Freescale format, Revised PQFN drawing, made several minor spelling correction. Added 33887A</li> </ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| 11.0     | 11/2006 | <ul style="list-style-type: none"> <li>Updated Ordering information block with new epp information</li> <li>Changed the supply/ operating voltage from 40 V to 28 V</li> <li>Updated all package drawings to the current revision</li> <li>Adjusted to match device performance characteristics</li> <li>Updated the document to the prevailing Freescale form and style</li> <li>Removed Peak Package Reflow Temperature During Reflow (solder reflow) parameter from <a href="#">Maximum Ratings on page 7</a>.</li> <li>Added note <sup>(8)</sup></li> <li>Added MCZ33887EK/R2 to the Ordering Information on Page 1</li> <li>Removed the 33887A from the data sheet and deleted Product Variation section now that is no longer needed.</li> </ul> |
| 12.0     | 1/2007  | <ul style="list-style-type: none"> <li>Changed the third paragraph of the introduction on page 1</li> <li>Altered feature number 1 on page 1</li> <li>Added feature number 2 on page 1</li> <li>Changed Maximum <a href="#">Supply Voltage <sup>(1)</sup></a> to 0.3 to 40 V</li> <li>Added note <sup>(1)</sup></li> <li>Changed note <sup>(16)</sup></li> <li>Added a third paragraph to <a href="#">Positive Power Supply (V+) on page 21</a></li> <li>Replaced <a href="#">Figure 20</a>, <a href="#">Figure 21</a>, and <a href="#">Figure 22</a> with updated information.</li> </ul>                                                                                                                                                             |
| 13.0     | 10/2008 | <ul style="list-style-type: none"> <li>Added Part Number MC33887AVW/R2 to Ordering Information Table on page 1.</li> </ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |

## **How to Reach Us:**

### **Home Page:**

[www.freescale.com](http://www.freescale.com)

### **Web Support:**

<http://www.freescale.com/support>

### **USA/Europe or Locations Not Listed:**

Freescale Semiconductor, Inc.  
Technical Information Center, EL516  
2100 East Elliot Road  
Tempe, Arizona 85284  
+1-800-521-6274 or +1-480-768-2130  
[www.freescale.com/support](http://www.freescale.com/support)

### **Europe, Middle East, and Africa:**

Freescale Halbleiter Deutschland GmbH  
Technical Information Center  
Schatzbogen 7  
81829 Muenchen, Germany  
+44 1296 380 456 (English)  
+46 8 52200080 (English)  
+49 89 92103 559 (German)  
+33 1 69 35 48 48 (French)  
[www.freescale.com/support](http://www.freescale.com/support)

### **Japan:**

Freescale Semiconductor Japan Ltd.  
Headquarters  
ARCO Tower 15F  
1-8-1, Shimo-Meguro, Meguro-ku,  
Tokyo 153-0064  
Japan  
0120 191014 or +81 3 5437 9125  
[support.japan@freescale.com](mailto:support.japan@freescale.com)

### **Asia/Pacific:**

Freescale Semiconductor Hong Kong Ltd.  
Technical Information Center  
2 Dai King Street  
Tai Po Industrial Estate  
Tai Po, N.T., Hong Kong  
+800 2666 8080  
[support.asia@freescale.com](mailto:support.asia@freescale.com)

### **For Literature Requests Only:**

Freescale Semiconductor Literature Distribution Center  
P.O. Box 5405  
Denver, Colorado 80217  
1-800-441-2447 or 303-675-2140  
Fax: 303-675-2150  
[LDCForFreescaleSemiconductor@hibbertgroup.com](mailto:LDCForFreescaleSemiconductor@hibbertgroup.com)

RoHS-compliant and/or Pb-free versions of Freescale products have the functionality and electrical characteristics of their non-RoHS-compliant and/or non-Pb-free counterparts. For further information, see <http://www.freescale.com> or contact your Freescale sales representative.

For information on Freescale's Environmental Products program, go to <http://www.freescale.com/epp>.

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale™ and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.

© Freescale Semiconductor, Inc., 2007 - 2008. All rights reserved.